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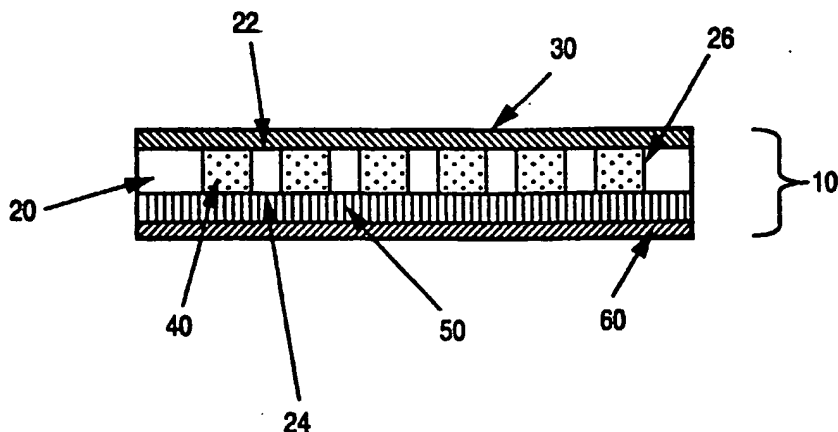
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- (74) Agent: COX, Scott, R.; Lynch, Cox, Gilman & Mahan, P.S.C., 400 West Market Street, Suite 2200, Louisville, KY 40202 (US).
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- (71) Applicant: SUD-CHEMIE, INC. [US/US]; P.O. Box 32370, 1600 W. Hill Street, Louisville, KY 40232-2370 (US).
- For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.
- (72) Inventors: DICK, Stefan; 8204 William Moyers Ave., NE, Albuquerque, NW 87122 (US). ROBERTSON, Andrew, J.; 900 Lagunayra NE, Albuquerque, NM 87108 (US).

(54) Title: IRREVERSIBLE HUMIDITY INDICATOR CARDS



(57) Abstract: An irreversible humidity indicator card comprising an intermediate carrier member containing one or more holes, a clear, water vapor permeable first outer layer secured to the first side of the carrier member, a deliquescent material contained within the holes in the carrier member, a dark colored, absorbent sheet material secured to the back side of the carrier member to cover the holes in the carrier member and a second outer layer which covers the colored absorbent sheet material and a portion or all of the back side of the intermediate carrier member.

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(54) Inhibitor parcel and method for preserving electronic devices or electronic parts.

(57) Disclosed are an inhibitor parcel comprising (a) a composition comprising an unsaturated fatty acid compound as its main ingredient and (b) a permeable diffusing-parcelling material prepared by laminating and bonding an oxygen-permeable resin layer onto one side of a base sheet made of a fibrous material and an adhesive or onto one adhesive-coating side of a base sheet made of a fibrous material, then laminating and bonding thereonto an oxygen-permeable resin layer and laminating and bonding a porous film of low softening point resin or a low softening point unwoven fabric onto the other side of the base sheet, said permeable diffusing-parcelling material (b) having an oxygen permeability of  $10^4$  to  $10^6$  ml/m<sup>2</sup>·Atm·Day and a (water vapor permeability/oxygen permeability) ratio of 0.02 [H<sub>2</sub>O mg·Atm/O<sub>2</sub> ml] or above at 25 °C at a relative humidity of 50% and said composition (a) being parcelled by said permeable diffusing-parcelling material (b) and an inhibitor parcel for use in electronic devices and electronic parts which comprises said inhibitor parcel and a method for preserving electronic devices and electronic parts using said inhibitor parcel.

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00889084 \*\*Image available\*\*

**IRREVERSIBLE HUMIDITY INDICATOR CARDS**

**CARTES INDIQUANT L'HUMIDITE DE MANIERE IRREVERSIBLE**

Patent Applicant/Assignee:

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Detailed Description

Claims

Fulltext Word Count: 4853

English Abstract

An irreversible **humidity indicator** card comprising an intermediate carrier member containing one or more holes, a clear, water vapor permeable first outer layer secured to the first side of the carrier member, a deliquescent material contained within the holes in the carrier member, a dark colored, absorbent sheet material secured to the back side of the carrier member to cover the holes in the carrier member and a second outer layer which covers the colored absorbent sheet material and a portion or all of the back side of the intermediate carrier member.

French Abstract

Une carte indiquant l'humidite de maniere irreversible comprend un element formant support intermediaire comprenant un ou plusieurs trous, une premiere couche externe transparente permeable a la vapeur d'eau fixee sur le premier cote de l'element formant support, un materiau deliquescent loge dans les trous de l'element formant support, un materiau en feuille, absorbant, de couleur sombre fixe sur le cote arriere de l'element formant support destine a recouvrir les trous formes dans l'element formant support et une deuxieme couche externe qui recouvre le materiau en feuille, absorbant, colore et une partie ou la totalite du cote arriere de l'element formant support intermediaire.

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# IRREVERSIBLE HUMIDITY INDICATOR CARDS

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Detailed Description

Claims

English Abstract

An irreversible humidity indicator card comprising an intermediate carrier member containing one or more holes, a clear, water vapor...

Publication Year: 2002

Detailed Description

Title

IRREVERSIBLE HUMIDITY INDICATOR CARDS

Background of the Invention

1. Field of the Invention

This invention relates to. humidity indicator cards and more particularly, to an irreversible humidity indicator card, which is covered on both sides, which utilizes a deliquescent material which does not...

...To address the need for the detection of humidity levels within shipping or storage containers, humidity indicators have been developed. There are generally two types of humidity indicators. One of these humidity indicators reversibly changes color upon exposure to particular humidity levels. Such reversible humidity indicators typically utilize cobalt chloride as the humidity indicator material. It changes color when exposed to predetermined levels of humidity and returns to its original color when the humidity level drops below that predetermined level. These reversible humidity indicators are used to indicate the current condition of a desiccant and/or the current humidity level within the storage container.

The second type of humidity indicator is an irreversible humidity indicator. These indicators are designed to detect a predetermined level of humidity and provide a visual indication of whether components stored in the containers where these humidity indicators are used have been exposed to that predetermined level of humidity even for short periods...

...falls dramatically depending upon the temperature of the surrounding air. Under these conditions, a reversible humidity indicator might fail to indicate the temporary presence of high humidity within a storage container even...

...cause damage to the components present in the storage container.

One of the first irreversible humidity indicator

2

devices was disclosed in U. S. Patent No. 2, 214, 354, which disclosed the...

...maintain a consistently low humidity level, shipping containers and long term storage containers usually contain

**desiccant** materials. These **desiccant** materials dehydrate the storage area and are intended to maintain the humidity level within that...

...area at a predetermined level.

These containers are periodically opened to recharge or replace the **desiccant** materials placed within the container and/or to check the level of humidity in the storage container. After replacing the **desiccant** material, the container is again sealed. In order to determine whether the humidity level in these storage containers has ever reached certain critical levels, irreversible **humidity indicators** are also often placed within the containers with

3

the **desiccant** materials. These irreversible **humidity indicators** can be reviewed at the same time that the **desiccant** material is being checked to determine whether a harmful humidity level has ever been reached in the shipping container.

A series of relative **humidity indicators**, each utilizing a different deliquescent salt, are disclosed in a series of patents which were...

...2f460f070r 2f460r071r

2r460f072r 2f460r073r 2F460r074r 2r526,938r 2f580,737f and 2f627,505. In addition, some **humidity indicator** cards are capable of showing different levels of humidity on the same card by use...

...color at varying humidity levels, as disclosed in U.S. Patent No. 2,249,867.

**Humidity indicator** sheets and cards which contain deliquescent salts and dyes have commonly been used to detect...

...U.S. Patent Nos. 2,249,867,

4r034f609r 4f1S0,570, and 4,854f160. Button-type **humidity indicators** or 'plug' **humidity indicators** are also sometimes used with packaging material and are disclosed, for example, by U.S...

...containing a reflective layerf which is useful in viewing the changes in color of a **humidity indicator** card is disclosed by U.S. Patent No. 4f034r609.

A reversible **humidity indicator** card contained within tran'sparentf flexible sheet materials with an impermeable front layer is disclosed in U.S. Patent No. 5,224,373. This **humidity indicator** card is specifically designed for utilization with **electronic components**. It is formed as a NN window' in a barrier **bag**.

A delayed action, irreversible **humidity indicator** card is disclosed in U.S. Patent No. 4f793f180.

All irreversible **humidity indicator** cards known hitherto are based on combinations of deliquescent salts and water-soluble dyes. In order to prepare **humidity indicator**

cards that react at various humidity levels, different combinations of deliquescent salts and dyes must...to determine whether a particular humidity level has been reached. W.B. Abel: Chemical Maximum **Humidity Indicator** Update Report, BDX 1989 and U.S. 3,r898r172 teach that only certain combinations of...

- ...salts with the dye is an additional required step for the production of the irreversible **humidity indicators** previously known. If the chosen salt and dye have different particle sizes, inhomogeneous distribution of...
- ...may occur and lead to inhomogeneous color and appearance on the indicating spot of the **humidity indicator**. This problem can be overcome by milling salt and dye together, but this is not...
- ...melt can cause corrosion to the products stored in the shipping containers in which the **humidity indicator** cards are utilized.

In addition, the blotter paper used to form

6

conventional **humidity indicator** cards sometimes sheds paper fibers and lint. Such fibers and lint may damage products that...

- ...as electronic components.

Accordingly, it is an object of this invention to produce an irreversible **humidity indicator** card which solves the problems present with conventional irreversible **humidity indicator** cards.

It is a still further object of the invention to disclose an irreversible **humidity indicator** card which is formed of a composite structure which includes a darkened blotter paper which...

- ...level of humidity.  
It is a further object of the invention to disclose an irreversible **humidity indicator** card which does not use a dye with its deliquescent material.

It is a further object of the invention to disclose an irreversible **humidity indicator** card which does not produce paper fibers or lint when in use.

#### Summary of the Invention

This invention is directed to an irreversible **humidity indicator** card comprising an intermediate carrier member, containing front and back sides and one or more...

- ...permeable first outer material and/or the second outer layer further comprise materials with anti- **static** and/or **electrostatic** charge dissipative properties.

The invention is also directed to a process for the production of the above-referenced irreversible **humidity indicator** card comprising preparing an intermediate carrier member containing a front and back side and one...

...member.

#### Brief Description of the Drawings

Figure 1 is a side view of the irreversible **humidity indicator** card of the invention.

Figure 2 is a perspective, exploded front view of the irreversible **humidity indicator** card.

Figure 3 is a back view of the irreversible **humidity indicator** card without the second outer layer (60).

#### Description of a Preferred Embodiment

Referring to Figures 1, 2 and 3, the invention is an

9

irreversible **humidity indicator** card (10) comprised of an intermediate carrier member (20), a first outer layer (30), deliquescent...

...member  
(20).

The intermediate carrier member is preferably formed from a single sheet of a **moisture absorbent** material, such as a conventional blotter paper. One or more ...and placement of the holes (26) dependent on the need of the manufacturer of the **humidity indicator** cards (10).

10

Written information informing the user of the **humidity indicator** card (10) about the humidity levels determined by the **humidity indicator** card (10) is generally printed on the front side (22) of the intermediate carrier member...

...humidity level of the surrounding air within the time predetermined by the manufacturer of the **humidity indicator** card (10). One preferred first outer layer (30) is a thin cellophane material. Alternatively, a...

...The choice as to the particular deliquescent material (40) depends on the manufacturer of the **humidity indicator** card (10). A list of deliquescent salts that may be useful can be found in W.B. Abel.

"Chemical Maximum **Humidity Indicator** Update Report". BDX613-1989 and includes ZnC'21 ZnBr., ZnI . LiCl. LiBr,, LiI.

KC2H3O21 CaC...thin flexible PVC material is used.

In an alternative embodiment, the composition of the irreversible **humidity indicator** (10) also preferably includes a material which introduces **electrostatic** charge dissipating and/or anti- **static** properties to the

irreversible **humidity indicator** (10). The material which introduces **electrostatic** dissipating and/or anti- **static**

16

properties may be incorporated into the clear water vapor permeable first outer layer (30) and/or into the second outer layer (60). The material which introduces

**electrostatic** charge dissipating and/or anti- **static** properties is preferably selected from the group consisting of carbon products, anionic surfactants, cationic surfactants...

...30) and/or the second outer

layer (60) may consist of plastic material that is

**electrostatic** charge dissipative by nature, such as cellulose derivatives.

In the process of formation of the irreversible **humidity indicator** card (10). the intermediate carrier member (20), which is preferably a conventional blotting paper, is...

...outer layer (30).

18

In use, this card (20) can be placed in a shipping **container** or storage **container** for equipment, preferably electronic equipment or **electronic components**, such as **integrated circuits**. Humidity present in the air within the **container** passes through at least the clear,, water vapor permeable, first outer layer (30) to be...

...intermediate carrier member (20) only after the deliquescent material (50) liquifies. Once liquification occurs, the **humidity indicator** card (10) shows that the predetermined

#### Claim

1 An irreversible **humidity indicator** card, comprising an intermediate carrier member, containing one or more holes passing through the intermediate...

...of

the intermediate carrier member, which covers the colored, absorbent sheet material.

2 The irreversible **humidity indicator** card of Claim I wherein the water vapor permeable first outer layer further comprises a material exhibiting **electrostatic** charge dissipating or anti- **static** properties.

3 The irreversible **humidity indicator** card of Claim wherein the second outer layer further comprises a material exhibiting **electrostatic** charge dissipating or anti- **static** properties.

4 The irreversible **humidity indicator** card of Claim

21

, wherein the water vapor permeable, first outer layer is coated on one side with an adhesive material.

5 The irreversible **humidity indicator** card of Claim



I wherein the second outer layer is comprised of a water vapor permeable material.

6 The irreversible **humidity indicator** card of Claim 1 wherein the second outer layer is coated with an adhesive material.

7 The irreversible **humidity indicator** of Claim 1 wherein the second outer layer completely covers the back side of the intermediate carrier member.

8 The irreversible **humidity indicator** card of Claim 1 wherein the deliquescent material is selected from the group consisting of...

...two or more deliquescent salts with one or more non-ionic compounds.

9 The irreversible **humidity indicator** card of Claim 1 wherein the deliquescent material is white in color.

10 The irreversible **humidity indicator** card of Claim 1 further comprising a plurality of deliquescent materials,  
22  
each of which liquifies at a different, predetermined humidity level.

11 The irreversible **humidity indicator** card of Claim 1 wherein the deliquescent material does not include a dye material.

12 The irreversible **humidity indicator** card of Claim 1 wherein the clear, water vapor permeable first outer layer has a vapor transmission rate of at least about jg/ (M2 -day).

13 The irreversible **humidity indicator** card of Claim 1 wherein the colored, absorbent sheet material is produced from a colored blotting sheet.

14 The irreversible **humidity indicator** card of Claim 1 wherein the second outer layer covers the back side of the intermediate carrier member.

15 The irreversible **humidity indicator** card of Claim 1 wherein the second outer layer is secured at one or more...

...the clear,, water vapor permeable, first outer layer.

16 A process of manufacture of a **humidity indicator** card comprising  
preparing an intermediate carrier member  
containing one or more holes, a front side...

...intermediate carrier member with a second outer layer.

17 A process of manufacture of a **humidity indicator** card comprising  
preparing an intermediate carrier member  
containing one or more holes and a front...

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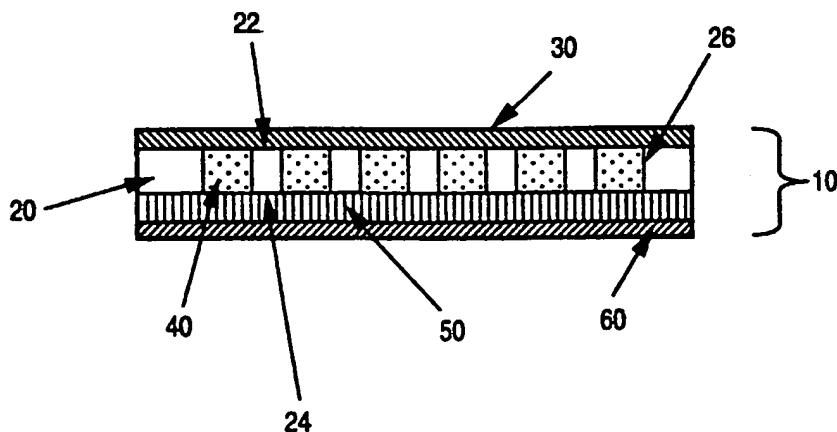
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- For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.
- (72) Inventors: DICK, Stefan; 8204 William Moyers Ave., NE, Albuquerque, NW 87122 (US). ROBERTSON, Andrew, J.; 900 Lagunayra NE, Albuquerque, NM 87108 (US).

(54) Title: IRREVERSIBLE HUMIDITY INDICATOR CARDS



(57) Abstract: An irreversible humidity indicator card comprising an intermediate carrier member containing one or more holes, a clear, water vapor permeable first outer layer secured to the first side of the carrier member, a deliquescent material contained within the holes in the carrier member, a dark colored, absorbent sheet material secured to the back side of the carrier member to cover the holes in the carrier member and a second outer layer which covers the colored absorbent sheet material and a portion or all of the back side of the intermediate carrier member.

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00848420 \*\*Image available\*\*

**AUTOMATED MANUFACTURING CONTROL SYSTEM**  
**SYSTEME AUTOMATISE DE CONTROLE DE FABRICATION**

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(EP) AT BE CH CY DE DK ES FI FR GB GR IE IT LU MC NL PT SE TR

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Main International Patent Class: G05B-019/418

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Detailed Description

Claims

Fulltext Word Count: 13208

**English Abstract**

An automated manufacturing control system is proposed to greatly reduce the human interaction relative to the data transfer, physical verification and process control associated with the movement of components, tooling and operators in a manufacturing system. This is achieved by the use of data carriers which are attached to the object(s) to be traced. These data carriers (12) can store all the relevant identification, material and production data required by the various elements, e.g. stations, of the manufacturing system. Various readers, integrated with controllers and application software, are located at strategic points of the production area, including production machines and storage areas, to enable automatic data transfer and physical verification that the right material is at the right place at the right time, using the right tooling.

**French Abstract**

L'invention concerne un systeme automatise de controle de fabrication permettant de reduire dans une large mesure l'interaction humaine relative aux transferts de donnees, aux verifications physiques et aux

contrôles de processus associés au déplacement des composants, à l'outillage et aux opérateurs dans un système de fabrication. Ce résultat est obtenu en utilisant des supports de données qui sont liés aux objets dont on veut suivre la localisation. Ces supports de données (12) peuvent mémoriser toutes les données appropriées d'identification, de matériau et de production requises par les divers éléments, par exemple, postes de travail, du système de fabrication. Divers lecteurs, intégrés aux unités de contrôle et aux logiciels d'application sont localisés à des points stratégiques de la zone de production, y compris les machines de production et les aires d'entreposage pour permettre les transferts de données et les vérifications physiques automatiques, de façon que le matériau approprié soit à sa vraie place au moment voulu tout en utilisant l'outillage approprié.

Legal Status (Type, Date, Text)

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Correction 20021024 Corrected version of Pamphlet: pages 1-28, description, replaced by new pages 1-28; pages 29-38, claims, replaced by new pages 29-38; pages 1/9-9/9, drawings, replaced by new pages 1/9-9/9; due to late transmittal by the receiving Office  
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Patent: ... 20011101  
Fulltext Availability:  
Detailed Description  
Claims  
Publication Year: 2001

Detailed Description

... clip in accordance with a first embodiment of the present invention, shown mounted on an **electronic components ' tray** (that is offily partly illustrated)  
Fig. 3b is an enlarged elevational view of part of...reliable and convenient method of communication with the tags (transponders). It is customised for **plastic trays** and reels and the associated tags. The support 14 is a **plastic** enclosure that is ergonomically shaped to hold **trays** and, reels 16 and at the same time to support and protect the inain antenna...rear view thereof The clip 30 is made out of process compatible materials that are **ESD (electrostatic discharge)** sensitive,  
that can sustain at least 125 'C and that will not contaminate parts...42 that will acconunodate the transponder 12 temporarily. This pouch 42 is made out of **ESD** sensitive material, designed and sized to accept the transponder 12 easily, hold (inverted exclamation mark...  
...transponder 12  
to a flat surface.

Example of data structure : trans@ onder attached to a **tray** , such as **tray** 28 in

p  
Fig. 3a, with **electronic components** .

**Tray Identification**

Manufacturer

Part number

Revision or Engineering change number

Date code

Component Identification

Manufacturer

15...This was not previously possible due to the absence of material identification on a standard **plastic tray**. This information can also be listed on a computer display. This list Moisture sensitive components ...

...trays or reels, must be placed by the manufacturer inside of sealed dry bags with **desiccants** and **humidity indicators**. The bag seal date must be indicated on the label (Fig. 1).

Once these bags...

**Claim**

... as claimed in claim 3, wherein said at least one component is a moisture sensitive **electronic component** nonnally stored in a sealed **container** adapted to be opened at at least one predetennined stage of said plurality of stages...

28/5,K/11 (Item 11 from file: 349)  
DIALOG(R)File 349:PCT FULLTEXT  
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00844469 \*\*Image available\*\*

**DESICCANT CONTAINING PRODUCT CARRIER**  
**SUPPORTS DE PRODUITS RENFERMANT UN DESSICCATIF**

Patent Applicant/Assignee:

ADVANCED MICRO DEVICES INC, One AMD Place, Mail Stop 68, P.O. Box 3453,  
Sunnyvale, CA 94088-3453, US, US (Residence), US (Nationality)

Inventor(s):

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Mail Stop 68, P.O. Box 3453, Sunnyvale, CA 94088-3453, US,

Patent and Priority Information (Country, Number, Date):

Patent: WO 200178113 A1 20011018 (WO 0178113)

Application: WO 2000US30730 20001108 (PCT/WO US0030730)

Priority Application: US 2000543346 20000405

Designated States: CN JP KR SG

(EP) AT BE CH CY DE DK ES FI FR GB GR IE IT LU MC NL PT SE TR

Main International Patent Class: H01L-021/00

Publication Language: English

Filing Language: English

Fulltext Availability:

Detailed Description

Claims

Fulltext Word Count: 2380

English Abstract

Disclosed is a product carrier having a **desiccant** incorporated therein  
and a method for making the same. The inventive carrier reduces the  
number of steps required to package a semiconductor device.

French Abstract

L'invention concerne un support de produit incorporant un dessiccatif  
ainsi qu'un procede de preparation relatif. Ce support permet de reduire  
le nombre d'etapes necessaires a l'emballage d'un dispositif  
semi-conducteur.

Legal Status (Type, Date, Text)

Publication 20011018 A1 With international search report.

Examination 20020110 Request for preliminary examination prior to end of  
19th month from priority date

**DESICCANT CONTAINING PRODUCT CARRIER**

Patent and Priority Information (Country, Number, Date):

Patent: ... 20011018

Fulltext Availability:

Detailed Description

Claims

English Abstract

Disclosed is a product carrier having a **desiccant** incorporated therein  
and a method for making the same. The inventive carrier reduces the  
number...

Publication Year: 2001

Detailed Description

**DESICCANT CONTAINING PRODUCT CARRIER**

## TECHNICAL FIELD

The present invention relates to a product carrier that has a **desiccant** incorporated therein.

The present invention is particularly applicable in reducing the steps required to package...

...of product quality from the factory floor to the customer 1 0 are required.

Some **IC packages** are susceptible to moisture induced damage. The risk of this is highest when plastic encapsulation materials are used, as **plastic** is naturally permeable to moisture. The moisture in the **package** will increase or decrease to reach the Relative Humidity (RH) of the surrounding environment.

1...

...circuits includes baking the integrated circuit devices until dry, placing them into a water and **humidity proof** packaging bag which contains **desiccant** packets and a **humidity indicator** card, sealing the bag immediately, and then shipping the device to the customer in these...

...etc.).

Dry packing protects product from environmental moisture by maintaining the interior of the **dry pack** bag at (less than or equal to) 20 percent RH. Included in the **dry pack** bag are a prescribed number of **desiccant** pouches. The **desiccant** pouches greatly reduce the presence of moisture.

## 0 SUNDARY OF THE INVENTION

There exists a...

...invention, a carrier for a semiconductor device is provided. The carrier includes a material containing **desiccant** particles embedded therein and a holding region for the semiconductor device.

Another aspect of the present invention provides a method for manufacturing such a semiconductor **carrier**. The method includes the steps of mixing a **desiccant** with molten **plastic** and molding the mixture into a product **carrier**.

Other objects and advantages of the present invention will become readily apparent to those skilled...

## ...INVENTION

An embodiment of the present invention is illustrated in Fig. 1, wherein the product **carrier** is a **tray 20** formed from a material, e.g., **plastic**. It will be appreciated that other materials suitable for forming relatively thin, sturdy structures can...

...form tray 20. Exemplary materials include, for example, conductive thermoplastic, non-conductive and insulated plastic, **antistatically** coated PVC, **antistatically** coated polysulfone (to provide protection from **ESD** damage and to eliminate the potential for low leakage between component leads), conductive carbon-filled **polypropylene**, and black dissipative BPI-10 **plastic**. In certain embodiments, the **carrier** material can withstand temperatures up to about 40°C to about 60°C, for example...

...C to 150°C. The material can also include a carbon-based material or be **antistatically** coated to provide **ESD** protection.

With continued reference to Fig. 1. **desiccant** particles 25 are embedded within tray 20. A preferred **desiccant** is **montmorillonite** (bentonite) clay. Tray 20 includes a notched corner 25, a flat or open bottom 27... skill in the art will appreciate that the present invention is not limited to product **carriers** for any particular **IC package** style. Rather, the product **carriers** of the present invention may be configured to accommodate, for example, Pin Grid Arrays (PGAs...

...and the sixth serving as a cover. Bound trays may then be loaded into an **antistatic** bubble pack bag, for extra cushioning protection, and then packed in a tray box for shipment.

Because a **desiccant** is incorporated directly into the product carrier, it is unnecessary to include separate **desiccant** packets in the packaging bag.

Fig. 2 is a flow diagram illustrating the method for...

...0 with an embodiment of the present invention. Referring to Fig. 2 at step 200, **desiccant** particles, such as **montmorillonite** (bentonite) clay, are mixed with molten plastic. At step 210, the molten **plastic** with **desiccant** particles mixed therein is molded into the product **carrier**, as with conventional techniques. One of ordinary skill in the art will appreciate that the amount of **desiccant** mixed with the molten plastic will be sufficient to greatly reduce the presence of moisture in a **dry pack** bag (i.e., 1 5 moisture barrier **bag**). For example, the amount of **desiccant** mixed with the molten **plastic** can be optimized such that there are about 32 grams of clay to about 64 grams of clay per **dry pack bag**.

Alternatively, the amount of **desiccant** mixed with the molten **plastic** can be optimized such that the environment in the **bag** is maintained at no greater than 20 percent RH, thus protecting the devices during shipment...

...only if the RH in the bag has exceeded 30 percent, as evidenced by a **humidity indicator** card.

Upon determination that a product is moisture sensitive, the product is dry packed for...

...type of product carrier (e.g., tubes, trays, reels, etc.).

The first step in the **dry pack** process is to remove any moisture buildup in the package by baking the finished product...

...aluminum trays or tubes. Within 50 hours after baking, the product is sealed in a **dry pack** bag under a partial vacuum.

An exemplary **dry pack** bag (i.e., moisture barrier bag) is designed with three layers. The inner layer is a low-density polyethylene, which has a **static**-dissipative coating. A second layer is 400 angstroms aluminum metallized to 92-gauge polyester. The third layer is 400 angstrom aluminum metallized to 92-gauge polyester, which has a **static**-dissipative coating. **ESD** protection is provided by the inner layer of **antistatic** polyethylene and the second layer of aluminum metallized polyester.



The bag is sealed using an...

...psi; and a temperature range of about 191 to about 232'C.

Included in each **dry pack** bag is a card that has humidity sensitive elements which turn from blue to pink...

...specific RH level is exceeded.

Labels may also be applied to the outside of the **dry pack** bag. For example, a standard product label, which identifies the contents by manufacturing lot number...

...part number, and the product date code(s) and quantity per date code.

Also, a **dry pack** caution label, which identifies the date the bag was sealed, the **dry pack** expiration date (which is 12 months later)), as well as product handling guidelines. A small...

#### Claim

1 - A carrier for a semiconductor device, the carrier comprising:  
a material containing a **desiccant** embedded therein; and  
a holding region for the semiconductor device.

2 The carrier of claim 1, wherein the **desiccant** is **montmorillonite** (bentonite) clay.

3 The carrier of claim 1, wherein the material can withstand temperatures from...

...manufacturing a carrier for a semiconductor device, the method comprising the steps of.

mixing a **desiccant** with molten **plastic** ;  
molding the mixture into a product **carrier** .  
loading a device into the product carrier; and  
dry packing the loaded product carrier in a bag.

9 The method of claim 8, comprising:  
mixing sufficient **desiccant** with the molten **plastic** such that the dry packed product **carrier** comprises from about 32 grams of **desiccant** to about 64 grams of **desiccant** .

10. The method of claim 8, comprising:  
mixing sufficient **desiccant** with the molten **plastic** such that an environment within the dry packed **bag** is maintained at no greater than about 20 percent relative humidity for about 12 months...

...packed bag.

15 The method of claim 8, further comprising:  
labeling an outside of the **dry pack** bag;  
packing the **dry pack** bag in a box; and  
labeling an outside of the box with a moisture-sensitivity...

Set	Items	Description
S1	323008	IC OR INTEGRATED()CIRCUIT?
S2	92396	(CIRCUIT OR SILICON OR SEMICONDUCT?R OR SEMI()CONDUCT?R OR ELECTRONIC) () (CHIP OR CHIPS OR COMPONENT?)
S3	5400	SMD OR SURFACE()MOUNT?()DEVICE?
S4	447871	PACKAGE? OR PACK OR PACKS OR PLCC OR QFP
S5	423265	TRAY OR TRAYS OR TUBE OR TUBES
S6	519569	RECEPTACLE? OR CARRIER?
S7	281338	CONTAINER? OR BAG OR BAGS
S8	473605	ELECTROSTATIC? OR STATIC? OR ANTISTATIC? OR ESD OR ESC
S9	14914	DESSICAT? OR DESSICANT? OR DESICCAT? OR DESICCANT?
S10	281	DRIBOX OR DRI()BOX OR DRYBOX OR DRY()BOX OR DRIPACK OR DRI- ()PACK OR DRYPACK OR DRY()PACK OR DRIPAK OR DRI()PAK OR DRYPAK OR DRY()PAK
S11	5727	(MOISTURE OR HUMIDITY) () (PROOF OR ABSORB? OR ADSORB? OR AB- SORP? OR ADSORP?)
S12	56094	MONTMORILLONITE OR SILICA()GEL OR MOLECULAR()SIEVE?
S13	17858	CALCIUM() (OXIDE OR SULFATE) OR ACTIVATE?()ALUMIN? OR ALUMI- N?()SILICA?
S14	1905	(HUMIDITY OR MOISTURE) () (INDICAT?R? OR MONITOR?) OR HUMITE- CT? OR COBALT()CHLORIDE
S15	40417	POLY() (STYRENE OR PROPYLENE OR VINYL OR AMIDE)
S16	809597	POLYSTYRENE OR POLYPROPYLENE OR POLYMER OR POLYVINYL OR PO- LYAMIDE
S17	765833	ELASTOMER OR PLASTIC? ?
S18	38347	S1:S3 AND S4:S7
S19	6	S18. AND S8 AND S9:S13
S20	9	S18 AND S14
S21	38347	S18 AND S15:S18(5N)S4:S7
S22	2418	S18 AND S15:S17(5N)S4:S7
S23	87	S22 AND S8
S24	1	S23 AND (S9:S13 OR S14)
S25	15	S19:S20 OR S24
S26	15	RD (unique items)
S27	15	S26 AND PY<2003

? show files

File 94:JICST-EPlus 1985-2003/Nov W5  
(c)2003 Japan Science and Tech Corp(JST)

File 95:TEME-Technology & Management 1989-2003/Nov W2  
(c) 2003 FIZ TECHNIK

File 99:Wilson Appl. Sci & Tech Abs 1983-2003/Oct  
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File 484:Periodical Abs Plustext 1986-2003/Nov W4  
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27/5,K/1 (Item 1 from file: 94)

DIALOG(R)File 94:JICST-EPlus

(c)2003 Japan Science and Tech Corp(JST). All rts. reserv.

04047208 JICST ACCESSION NUMBER: 99A0336175 FILE SEGMENT: JICST-E

IC with humidity indicator .

YAMADA MANABU (1)

(1) Toshiba Corp.

Toshiba Gijutsu Kokaishu, 1999 , VOL.17,NO.21, PAGE.101-102, FIG.2

JOURNAL NUMBER: L0795AAY ISSN NO: 0288-2701

UNIVERSAL DECIMAL CLASSIFICATION: 621.315.5

LANGUAGE: Japanese COUNTRY OF PUBLICATION: Japan

DOCUMENT TYPE: Journal

ARTICLE TYPE: Commentary

MEDIA TYPE: Printed Publication

DESCRIPTORS: **integrated circuit** ; surface mount technology; **IC**

**package** ; moisture proof packaging; wrapping; humidity sensor

BROADER DESCRIPTORS: micro circuit; high density packaging;

packaging(mounting); **container** ; packaging; packaging technology;

hygrometer; meteorological instrument; sensor; instrumentation element

CLASSIFICATION CODE(S): NC03020K

IC with humidity indicator .

, 1999

DESCRIPTORS: **integrated circuit** ; ...

... **IC package** ;

...BROADER DESCRIPTORS: **container** ;

27/5,K/2 (Item 2 from file: 94)

DIALOG(R)File 94:JICST-EPlus

(c)2003 Japan Science and Tech Corp(JST). All rts. reserv.

03560419 JICST ACCESSION NUMBER: 98A0352954 FILE SEGMENT: JICST-E

**Semiconductor devices.**

HARADA HIDEAKI (1)

(1) Toshiba Corp.

Toshiba Gijutsu Kokaishu, 1998 , VOL.16,NO.17, PAGE.151-152, FIG.1

JOURNAL NUMBER: L0795AAY ISSN NO: 0288-2701

UNIVERSAL DECIMAL CLASSIFICATION: 621.315.5

LANGUAGE: Japanese COUNTRY OF PUBLICATION: Japan

DOCUMENT TYPE: Journal

ARTICLE TYPE: Commentary

MEDIA TYPE: Printed Publication

DESCRIPTORS: **IC package** ; desiccant; **cobalt chloride** ; hygroscopic  
coefficient; moisture proofing; display

BROADER DESCRIPTORS: **container** ; chloride; chlorine compound; halogen

compound; halide; cobalt compound; iron group element compound;

transition metal compound; coefficient; soil moisture constant;

constant; soil moisture property; moisture characteristic;

characteristic; physical property of soil; soil property;

preclusion(protection

CLASSIFICATION CODE(S): NC03020K

, 1998

DESCRIPTORS: **IC package** ; ...

... **cobalt chloride** ;

BROADER DESCRIPTORS: **container** ;

27/5,K/3 (Item 3 from file: 94)  
DIALOG(R)File 94:JICST-EPlus  
(c)2003 Japan Science and Tech Corp(JST). All rts. reserv.

01784858 JICST ACCESSION NUMBER: 93A0547233 FILE SEGMENT: JICST-E  
**Accurate 3D Capacitance Evaluation in Integrated Capacitive Humidity  
Sensors.**

KORVINK J G (1); CHANDRAN L (1); BOLTSHAUSER T (1); BALTES H (1)  
(1) ETH-Hoenggerberg, Zuerich, CHE  
Sens Mater, 1993, VOL.4,NO.6, PAGE.323-335, FIG.7, TBL.1, REF.15  
JOURNAL NUMBER: L0338AAP ISSN NO: 0914-4935 CODEN: SENME  
UNIVERSAL DECIMAL CLASSIFICATION: 621.382+  
LANGUAGE: English COUNTRY OF PUBLICATION: Japan  
DOCUMENT TYPE: Journal  
ARTICLE TYPE: Original paper  
MEDIA TYPE: Printed Publication

ABSTRACT: We describe progress made towards the accurate 3-D modelling of integrated capacitive humidity microsensors fabricated using industrial CMOS technology. The designs are based on microelectrodes coated with a **moisture - absorbing** polyimide layer. A new dedicated software **package**, semiconductor sensor device simulation (SESES), has been developed for this purpose. It solves the 3-D Poisson equation over the full sensor structure, subject to appropriate boundary conditions, using the finite-element method. The solution determines the induced surface charge on the electrodes and hence the exact capacitance, which can then be used for 'dielectric modelling', namely, to assess the accuracy of various models of dielectric behaviour in the polyimide, from a comparison with experimental results. We also describe progress made in the optimization of sensor design, particularly in improving the sensitivity to humidity. We outline how SESES can also be used for the careful study of reliability considerations, such as the effects of embedded charges. Our results are relevant to integrated microsensors in general, i.e., any application involving capacitance measurements. (author abst.)

DESCRIPTORS: humidity sensor; polyimide; CMOS structure; **electrostatic** capacity; sensitivity(ratio); computer simulation; Poisson equation; finite element method; modeling; dielectric thin film; polymer membrane; semiconductor **integrated circuit**; surface charge

BROADER DESCRIPTORS: hygrometer; meteorological instrument; sensor; instrumentation element; polymer; MOS structure; device structure; capacity; sensitivity; property; degree; computer application; utilization; simulation; differential equation; equation; formula; approximation method; operation(processing); thin film; membrane and film; dielectrics; dielectric material; material; functional polymer; macromolecule; **integrated circuit**; micro circuit; electric charge

CLASSIFICATION CODE(S): NC03150A

, 1993

...ABSTRACT: microsensors fabricated using industrial CMOS technology. The designs are based on microelectrodes coated with a **moisture - absorbing** polyimide layer. A new dedicated software **package**, semiconductor sensor device simulation (SESES), has been developed for this purpose. It solves the 3...

...DESCRIPTORS: **electrostatic** capacity...

...semiconductor **integrated circuit**;

...BROADER DESCRIPTORS: **integrated circuit**;

27/5,K/4 (Item 1 from file: 99)  
DIALOG(R)File 99:Wilson Appl. Sci & Tech Abs

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1174349 H.W. WILSON RECORD NUMBER: BAST94042956

**Packaging electronics is more than damage control**

Baum, Chris;

Packaging (Boston, Mass.) v. 39 (June '94) p. 24

DOCUMENT TYPE: Feature Article ISSN: 0746-3820 LANGUAGE: English

RECORD STATUS: New record

**ABSTRACT:** Because packaging-quality problems can affect not only a product's effectiveness but also a company's reputation, VLSI Technology turned to United Desiccants for help in packaging its sensitive circuitry. VLSI developed a vacuum-sealed, barrier **bag** to contain its Metric Quad Flat **Pack**, which holds the microprocessor chips. Six special plastic **trays** are stacked and placed into the barrier **bag** together with United Desiccants' Desi Pak moisture-adsorbing desiccant and an **SMD - Humitector** humidity-indicating card.

**DESCRIPTORS:** Packing for shipment; Drying agents; Electronic apparatus and instruments--Protection;

...**ABSTRACT:** United Desiccants for help in packaging its sensitive circuitry. VLSI developed a vacuum-sealed, barrier **bag** to contain its Metric Quad Flat **Pack**, which holds the microprocessor chips. Six special plastic **trays** are stacked and placed into the barrier **bag** together with United Desiccants' Desi Pak moisture-adsorbing desiccant and an **SMD - Humitector** humidity-indicating card.

1994

27/5,K/5 (Item 1 from file: 6)

DIALOG(R)File 6:NTIS

(c) 2003 NTIS, Intl Cpyrght All Rights Res. All rts. reserv.

1545395 NTIS Accession Number: DE90017595

**Short and long loop manufacturing feedback using a multi-sensor assembly test chip**

Sweet, J. N. ; Tuck, M. R. ; Peterson, D. W. ; Palmer, D. W.

Sandia National Labs., Albuquerque, NM.

Corp. Source Codes: 068123000; 9511100

Sponsor: Department of Energy, Washington, DC.

Report No.: SAND-90-2033C; CONF-9010158-2

1990 17p

Languages: English Document Type: Conference proceeding

Journal Announcement: GRAI9104; NSA1500

IEEE/CHMT international electronics manufacturing technology symposium (9th), Washington, DC (USA), 1-3 Oct 1990. Sponsored by Department of Energy, Washington, DC.

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NTIS Prices: PC A03/MF A01

Country of Publication: United States

Contract No.: AC04-76DP00789

A three generation family of CMOS silicon test chips for packaging diagnostics has been developed. These Assembly Test Chips (ATC) contain sensors that measure a number of variables associated with assembled IC degradation, including the degree of IC corrosion, handling damage, ESD

threat, ppm, moisture, mechanical stress, mobile ion density, bond pad cratering, and high speed logic degradation. The ATC family are intended to give manufacturing feedback in four ways: direct feedback in evaluation of an Assembly Manufacturing Line in an objective, non-intrusive way; before and after comparisons on an assembly production line when an individual process, material, or piece of equipment has been changed; resident lifetime monitor for system **package** aging and ongoing reliability projection and thermal, mechanical, dc electrical, and high frequency mock-up evaluation of packaging (including multichip) schemes. 14 refs., 6 figs., 2 tabs. (ERA citation 15:049191)

Descriptors: **Integrated Circuits** ; \*Process Control; \*Diagnostic Techniques; \*Feedback; \*Packaging; Aging; Bonding; Corrosion; Damage; Design; Electrical Properties; Fabrication; Failure Mode Analysis; Layers; Measuring Methods; **Moisture** ; **Monitoring** ; Optimization; Reliability; Specifications; Stress Analysis; Structural Models

Identifiers: \*CMOS; \*Computer aided manufacturing; EDB/420500; EDB/426000 ; EDB/320303; Chips(Electronics); Assembly test chips; Sensors; Feedback control; Nondestructive testing; NTISDE

Section Headings: 49H (Electrotechnology--Semiconductor Devices); 41G (Manufacturing Technology--Quality Control and Reliability); 94J (Industrial and Mechanical Engineering--Nondestructive Testing); 41B (Manufacturing Technology--Computer Aided Manufacturing (CAM))

... Assembly Test Chips (ATC) contain sensors that measure a number of variables associated with assembled IC degradation, including the degree of IC corrosion, handling damage, ESD threat, ppm, moisture, mechanical stress, mobile ion density, bond pad cratering...

... individual process, material, or piece of equipment has been changed; resident lifetime monitor for system **package** aging and ongoing reliability projection and thermal, mechanical, dc electrical, and high frequency mock-up...

Descriptors: **Integrated Circuits** ; \*Process Control; \*Diagnostic Techniques; \*Feedback; \*Packaging; Aging; Bonding; Corrosion; Damage; Design; Electrical Properties; Fabrication; Failure Mode Analysis; Layers; Measuring Methods; **Moisture** ; **Monitoring** ; Optimization; Reliability; Specifications; Stress Analysis; Structural Models

27/5,K/6 (Item 1 from file: 8)  
DIALOG(R)File 8: Ei Compendex(R)  
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04883268 E.I. No: EIP97123944852

Title: **Test chip development to support standardization efforts**  
Author: Bright, Bill  
Corporate Source: Symbios Logic, Inc, Fort Collins, CO, USA  
Conference Title: Proceedings of the 1997 21st IEEE/CPMT International Electronics Manufacturing Technology (IEMT) Symposium  
Conference Location: Austin, TX, USA Conference Date: 19971013-19971015  
Sponsor: IEEE  
E.I. Conference No.: 47387  
Source: Proceedings of the IEEE/CPMT International Electronics Manufacturing Technology (IEMT) Symposium 1997. IEEE, Piscataway, NJ, USA, 97CH36068. p 184-191  
Publication Year: 1997  
CODEN: 61UNAI  
Language: English  
Document Type: CA; (Conference Article) Treatment: G; (General Review)  
Journal Announcement: 9801W4

Abstract: A test chip has been developed which integrates test structures for performing reliability testing, and thermal and electrical characterization on **packages** and assembly processes. This work supports test chip standardization efforts of the Semiconductor Assembly Council (SAC) and the JEDEC JC15 Electrical Measurements and Simulation Committee. For the purpose of reliability qualifications, several single-metal structures are provided to evaluate the environmental integrity of the **package**. Characterization structures, such as a capacitor for **moisture monitoring**, a strain gauge rosette, diodes, a heating resistor, and custom digital drivers have been integrated to quantify the mechanical, thermal, and electrical performance aspects of the **package**. This paper provides an overview of the test die functionality and discusses the application of each test sensor. (Author abstract) 10 Refs.

Descriptors: Electronics packaging; **Integrated circuit** testing; Standardization; Reliability; **Integrated circuit** manufacture; Capacitors; Moisture determination; Strain gages; Resistors; Dies  
Identifiers: Reliability testing; Strain gage rosettes

Classification Codes:

714.2 (Semiconductor Devices & Integrated Circuits); 902.2 (Codes & Standards); 913.3 (Quality Assurance & Control); 704.1 (Electric Components)

714 (Electronic Components); 902 (Engineering Graphics & Standards); 421 (Materials Properties); 913 (Production Planning & Control); 704 (Electric Components & Equipment)

71 (ELECTRONICS & COMMUNICATIONS); 90 (GENERAL ENGINEERING); 42 (MATERIALS PROPERTIES & TESTING); 91 (ENGINEERING MANAGEMENT); 70 (ELECTRICAL ENGINEERING)

...Abstract: developed which integrates test structures for performing reliability testing, and thermal and electrical characterization on **packages** and assembly processes. This work supports test chip standardization efforts of the Semiconductor Assembly Council...

...reliability qualifications, several single-metal structures are provided to evaluate the environmental integrity of the **package**. Characterization structures, such as a capacitor for **moisture monitoring**, a strain gauge rosette, diodes, a heating resistor, and custom digital drivers have been integrated to quantify the mechanical, thermal, and electrical performance aspects of the **package**. This paper provides an overview of the test die functionality and discusses the application of...

Descriptors: Electronics packaging; **Integrated circuit** testing; Standardization; Reliability; **Integrated circuit** manufacture; Capacitors; Moisture determination; Strain gages; Resistors; Dies

27/5,K/7 (Item 2 from file: 8)  
DIALOG(R)File 8:EI Compendex(R)  
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01025272 E.I. Monthly No: EI8106048462 E.I. Yearly No: EI81034333  
Title: **RECENT ADVANCES IN AI//20//3 " IN-SITU " MOISTURE MONITORING CHIPS FOR Cerdip PACKAGE APPLICATIONS.**  
Author: Finn, J. B.; Fong, V.  
Corporate Source: Mostek Corp, Carrollton, Tex  
Source: Annu Proc Reliab Phys Symp 18th, Las Vegas, Nev, Apr 8-10 1980.  
Publ by IEEE (Cat n 80CH1531-3), Piscataway, NJ, 1980 p 10-16  
Publication Year: 1980  
CODEN: ARLPBI ISSN: 0099-9512  
Language: ENGLISH  
Journal Announcement: 8106



Abstract: Determination of the internal water vapor of a Cerdip package can be conveniently and inexpensively performed by an Al//20//3 chip type sensor of recent design. Comparisons with an earlier design are made. Data of field trials by several IC manufacturers from common chip lots are shown. For the purpose of generating a broad range of moisture levels, both vitreous and nonvitreous sealing glass types were studied along with the effect of desiccants, lint contamination of the sealing glass, and the leak detection capability of the sensor. The relationship of sensor measured values with those of mass spectrometry is shown. 7 refs.

Descriptors: \*ELECTRONICS PACKAGING--\*Moisture Control; SENSORS

Classification Codes:

715 (General Electronic Equipment); 944 (Moisture, Pressure & Temperature, & Radiation Measuring Instruments)

71 (ELECTRONICS & COMMUNICATIONS); 94 (INSTRUMENTS & MEASUREMENT)

Title: RECENT ADVANCES IN Al//20//3 " IN-SITU " MOISTURE MONITORING CHIPS FOR CERDIP PACKAGE APPLICATIONS.

Abstract: Determination of the internal water vapor of a Cerdip package can be conveniently and inexpensively performed by an Al//20//3 chip type sensor of recent design. Comparisons with an earlier design are made. Data of field trials by several IC manufacturers from common chip lots are shown. For the purpose of generating a broad range...

27/5,K/8 (Item 3 from file: 8)

DIALOG(R) File 8: Ei Compendex(R)

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00895530 E.I. Monthly No: EI8002013051 E.I. Yearly No: EI80045513

Title: CHARACTERISTICS OF A SURFACE CONDUCTIVITY MOISTURE MONITOR FOR HERMETIC INTEGRATED CIRCUIT PACKAGES .

Author: Lowry, Robert K.; Miller, L. A.; Jonas, Allen W.; Bird, J. M.

Corporate Source: Harris Semicond, Melbourne, Fla

Source: Annu Proc Reliab Phys Symp 17th, San Francisco, Calif, Apr 24-26 1979. Publ by IEEE (Cat n 79CH1425-8PHY), New York, NY, 1979 p 97-102

Publication Year: 1979

CODEN: ARLPBI ISSN: 0099-9512

Language: ENGLISH

Journal Announcement: 8002

Abstract: An in-situ surface conductivity sensor for measuring water content of hermetic package ambients is described. Results of correlation experiments with mass spectroscopy and volume-effect sensors are presented. Sensor studies of water desorption and contamination by leached ions are discussed. The surface conductivity sensor is well-suited to defining moisture levels within all types of hermetic packages . 19 refs.

Descriptors: INTEGRATED CIRCUITS --\*Packaging; RELIABILITY

Classification Codes:

714 (Electronic Components); 713 (Electronic Circuits); 913 (Production Planning & Control); 421 (Materials Properties)

71 (ELECTRONICS & COMMUNICATIONS); 91 (ENGINEERING MANAGEMENT); 42 (MATERIALS PROPERTIES & TESTING)

Title: CHARACTERISTICS OF A SURFACE CONDUCTIVITY MOISTURE MONITOR FOR HERMETIC INTEGRATED CIRCUIT PACKAGES .

Abstract: An in-situ surface conductivity sensor for measuring water content of hermetic package ambients is described. Results of correlation experiments with mass spectroscopy and volume-effect sensors are...

...surface conductivity sensor is well-suited to defining moisture levels within all types of hermetic packages . 19 refs.

Descriptors: INTEGRATED CIRCUITS --\*

27/5,K/9 (Item 4 from file: 8)  
DIALOG(R)File 8:EI Compendex(R)  
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00393191 E.I. Monthly No: EI7409058752  
Title: **NEW SIMPLIFIED METHOD TO MEASURE MOISTURE IN MICRO ENCLOSURES.**  
Author: Zatz, Saul  
Corporate Source: Martin Marietta Aersop, Orlando, Fla  
Source: Electron Components Conf, 24th, Proc, Washington, DC, May 13-15  
1974 p29-33. Available from IEEE, New York, 1974  
Publication Year: 1974  
Language: ENGLISH  
Journal Announcement: 7409  
Abstract: A new technique has been perfected to accurately measure the moisture content in the small volumes typified by semiconductor and **integrated circuit packages**. The methodology uses an inexpensive, easily fabricated **moisture monitor** that incorporates two bond wires in a standard **package**. After **package** seal as part of a production seal run, the dew point can be directly and accurately measured. A recognized direct relationship exists between dew points and moisture content. Comparison with other techniques and life tests of moisture sensitive parts have demonstrated the validity and effectiveness of this approach. The new technique eliminates the gross errors that are introduced when the micro-volume is drawn into a large volume test manifold. This technique is currently being used to certify the process controls and seal effectiveness of critical **integrated circuits** for a high reliability system. 5 refs.  
Descriptors: \*SOLID STATE DEVICES--\*Electronics Packaging  
Classification Codes:  
714 (Electronic Components)  
71 (ELECTRONICS & COMMUNICATIONS)

...Abstract: perfected to accurately measure the moisture content in the small volumes typified by semiconductor and **integrated circuit packages**. The methodology uses an inexpensive, easily fabricated **moisture monitor** that incorporates two bond wires in a standard **package**. After **package** seal as part of a production seal run, the dew point can be directly and...

...technique is currently being used to certify the process controls and seal effectiveness of critical **integrated circuits** for a high reliability system. 5 refs.

27/5,K/10 (Item 1 from file: 484)  
DIALOG(R)File 484:Periodical Abs Plustext  
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05593594 SUPPLIER NUMBER: 127089781 (USE FORMAT 7 OR 9 FOR FULLTEXT)  
**Framing and flattering works of art on paper**  
Grant, Daniel  
Consumers' Research Magazine (GCRM), v85 n5, p24-28, p.5  
May 2002  
ISSN: 0095-2222 JOURNAL CODE: GCRM  
DOCUMENT TYPE: Feature  
LANGUAGE: English RECORD TYPE: Fulltext; Abstract  
WORD COUNT: 3893

ABSTRACT: The subject of framing of works of art occupies a lot of time for art dealers and even more for collectors. Two issues face collectors in displaying works on paper, and they are sometimes treated as mutually exclusive.

Copyright Consumers' Research Incorporated May 2002

DESCRIPTORS: Collectors; Art; Picture framing  
CODEN: CRMZA6

2002

TEXT:

... buy and for how much.

Most museums these days have quite high-tech temperature and **humidity monitoring** systems controlling the interior environment. That kind of control is less possible where people live...wide.

Conservators speak not only about framing and matting but also about the entire "frame **package** ." That **package** typically consists of backing material, a backboard, the drawing itself, a window mat, covering glass... Works, 1717 K Street, N.W., Washington, DC 20006, 202-452-9545, [www.aic-fa.ic.org](http://www.aic-fa.ic.org).

Daniel Grant

Mr. Grant is the author of several books on art, including The...

27/5,K/11 (Item 2 from file: 484)

DIALOG(R)File 484:Periodical Abs Plustext  
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04500517 (USE FORMAT 7 OR 9 FOR FULLTEXT)

Let's network some more

Fleck, Ken

Electronic News (IELN), v45 n40, p40, p.1

Oct 4, 1999

ISSN: 1061-6624 JOURNAL CODE: IELN

DOCUMENT TYPE: Commentary

LANGUAGE: English

RECORD TYPE: Fulltext; Abstract

WORD COUNT: 577

ABSTRACT: Fleck examines trends in packaging and high-speed digital circuitry, which are design challenges faced by the connector industry and new connector designs.

Copyright Electronic News Publishing Corp. 1999

DESCRIPTORS: Packaging; **Integrated circuits**

SPECIAL FEATURES: Photograph

1999

TEXT:

... Calif., now is offering its miniature wafer-level chip-scale packaging (CSP) technology, termed micro **SMD** , with an additional 13 of its analog products.

The semiconductors introduced last week target applications...

...size or weight constraints such as handheld and portable products. National first used the micro **SMD** technology a year ago to **package** a dual op amp.

"The 8-10 version of this new **package** occupies 85 percent less surface area than an 8-lead MSOP," said Pat Brockett, executive...

...SMDs. Thus, designers will be able to execute a complete system design using these tiny **packages**."

And the firm noted "since it is a wafer-level packaging process, a whole series..."

...process."

A patented encapsulation process on the front and back of the wafer produces a **packageless** device. Micro **SMD** products conform to standard JEDEC pinout patterns, assuring accurate circuit board placement using existing mounting equipment. Customers can transition to micro **SMD** parts without any retooling of their standard surface mount manufacturing equipment, National added.

"We tested the new micro **SMD** from National Semiconductor on Universal Instruments' GSM pick-- and-place system," said Jayson Noland, senior...

...Silicon Valley Technology Center we were able to pick, inspect and accurately place the micro **SMD** components with ease."

National also claimed micro **SMD** packaging yields more reliable components.

"Shorter interconnections result in low inductance and minimal signal degradation; micro **SMD** - **packaged** components actually meet or beat standard electrical characteristics. Micro **SMD packages** meet the level-1 specification for moisture sensitivity. No **dry pack**, nitrogen storage or bake is required. National's micro **SMD package** passed all mechanical and electrical tests, thermal cycles, solderjoint integrity, **ESD**, vibration and drop tests with zero failures. Moreover, unlike some surface mount **packages**, no underfill is required, simplifying and reducing production costs."

Today, National is delivering the LMC555...

...DESCRIPTORS: **Integrated circuits**

27/5,K/12 (Item 3 from file: 484)  
DIALOG(R)File 484:Periodical Abs Plustext  
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04500516 (USE FORMAT 7 OR 9 FOR FULLTEXT)

**National hikes wafer-level CSP use**

Anonymous

Electronic News (IELN), v45 n40, p40, p.1

Oct 4, 1999

ISSN: 1061-6624 JOURNAL CODE: IELN

DOCUMENT TYPE: News

LANGUAGE: English

RECORD TYPE: Fulltext; Abstract

WORD COUNT: 577

ABSTRACT: National Semiconductor Corp is offering its miniature wafer-level chip-scale packaging technology with an additional 13 of its analog products. The technology is called micro **SMD**.

Copyright Electronic News Publishing Corp. 1999

DESCRIPTORS: Semiconductors; Packaging

SPECIAL FEATURES: Illustration

COMPANY INFORMATION:

National Semiconductor Corp

1999

...ABSTRACT: packaging technology with an additional 13 of its analog

products. The technology is called micro **SMD** .

TEXT:

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27/5,K/13 (Item 4 from file: 484)  
DIALOG(R)File 484:Periodical Abs Plustext  
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03448960 (USE FORMAT 7 OR 9 FOR FULLTEXT)

**Magnetic field alignment of ordered silicate-surfactant composites and mesoporous silica**

Tolbert, Sarah H; Firouzi, Ali; Stucky, Galen D; Chmelka, Bradley F  
Science (GSCI), v278 n5336, p264-268, p.5

Oct 10, 1997

ISSN: 0036-8075 JOURNAL CODE: GSCI

DOCUMENT TYPE: Feature

LANGUAGE: English

RECORD TYPE: Fulltext; Abstract

WORD COUNT: 4016

ABSTRACT: Macroscopic orientational ordering of the pores of condensed hexagonal mesostructured silica was achieved through alignment of an unpolymerized, hexagonal, lyotropic silicate-surfactant liquid crystal in a high magnetic field.

Copyright American Association for the Advancement of Science 1997

DESCRIPTORS: Materials science; Chemistry; Magnetism; Silicon

SPECIAL FEATURES: References Graph Illustration Photograph

1997

TEXT:

... to consist of aggregates of assembled surfactant molecules that interact covalently (3, 8, 10) or **electrostatically** (1, 6, 8) with an inorganic framework. For densely cross-linked inorganic mesostructures, it is...

...separations, and chemical sensing of molecules that are too large for processing with crystalline zeolite **molecular sieves**, which generally have smaller (2 to 15 Angstrom) micropores. Mesoporous solids may also be used show that the spectrum in Fig. IC can be reproduced from a model in which 80% of the cetyltrimethylammonium ions (CTA+) reside...

...silicate-surfactant-rich phase, and the latter was exposed to concentrated HCl vapor in a closed **container** for 1 to 3 days at room temperature (27). After removal from the acid vapor...

...the results obtained from  $^2\text{H}$  NMR on the aligned liquid crystalline precursor (Fig. IC), indicating that long-range orientational ordering of the mesophase domains was not disrupted by polymerization...

27/5,K/14 (Item 5 from file: 484)

DIALOG(R)File 484:Periodical Abs Plustext

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03082700 (USE FORMAT 7 OR 9 FOR FULLTEXT)

**Narrativity, myth, and metaphor: Louise Erdrich and Raymond Carver talk about love**

Downes, Margaret J

MELUS (PMEL), v21 n2, p49-61, p.13

Summer 1996

ISSN: 0163-755X JOURNAL CODE: PMEL

DOCUMENT TYPE: Feature

LANGUAGE: English

RECORD TYPE: Fulltext; Abstract

WORD COUNT: 5340

ABSTRACT: Downes argues that love and narrative are similarly structured experiences. A narrative involves the reader with something more or less unfamiliar or elusive, something like love, and tells about it. Her discussion of Erdrich and Carver is admittedly idiosyncratic and interesting.

Copyright MELUS, Society for the Study of Multi-Ethnic Literature of the US 1996

DESCRIPTORS: Love; Literary criticism; Novels; Metaphor

NAMED PERSONS: Erdrich, Louise; Carver, Raymond

SPECIAL FEATURES: References

1996

TEXT:

... Harvard Medical School, remarks that "the brain works associatively. High-level associations are metaphors, which **pack** lots of material into an economic unit" (qtd. in Begley 44). Hobson is speaking here ...hereditary means of imposing psychological tyranny. But by myth I do not mean a monolithic, **static** and oppressive force which "fetter[s] linguistic consciousness" and exerts "absolute hegemony... over language" (Bakhtin...

...however, as variable and dynamic as are meaning and language. Those cultural myths which are **static** support savage societies which practice (in whatever form) ritual sacrifice. Such a society is essentially...

...myth because experience seems to pattern itself, and we cannot grasp experience unless it is **packaged** so. "Truth"-an evanescent thing is revealed when we discover and apply an appropriate structure, oftentimes... it talked out. After a time, she quit trying" (10). A late bloomer in her **desiccated** society, she finally has learned the futility, in that milieu, of trying to construct and...Recovering the Feminine in American Indian Traditions. Boston: Beacon, 1986.

Bakhtin, M. M. The Dialog-ic Imagination: Four Essays by M. M. Bakhtin. Ed. Michael Holquist. Trans. Caryl Emerson and Michael...

27/5,K/15 (Item 6 from file: 484)  
DIALOG(R)File 484:Periodical Abs Plustext  
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02218369 (USE FORMAT 7 OR 9 FOR FULLTEXT)

**Engineering for the ends of the Earth**

Valenti, Michael

Mechanical Engineering (GMEE), v116 n12, p56-60, p.5

Dec 1994

ISSN: 0025-6501 JOURNAL CODE: GMEE

DOCUMENT TYPE: Feature

LANGUAGE: English

RECORD TYPE: Fulltext; Abstract

WORD COUNT: 2993

LENGTH: Long (31+ col inches)

ABSTRACT: Scientists are using meteorological and oceanographic instruments, including thermistors and snow depth sensors, designed to withstand harsh conditions to study polar climates. The instruments are sensitive to the slightest variations in temperature, pressure, moisture and wind speed but can withstand harsh weather.

Copyright American Society of Mechanical Engineers 1994

DESCRIPTORS: Instruments; Climate; Meteorology; Research & development; R&D

SPECIAL FEATURES: Photograph

1994

TEXT:

... Project.

Engineers get around this problem in two ways, Zika explained: by locating the battery **packs** of their polar research systems out of the wind and as close to sea level...

...mounted on a pipe extended from a tower, is suspended over the snow. An ultrasonic **electrostatic** transducer emits 50 kHz sound pulses that bounce back to the sensor and are timed...pass through, and a closed piping system that interconnects the barometer and water trap with **desiccant** chambers

containing silica gel to keep the air dry.

The Ice Platform measures the air temperature with a thermistor contained in a watertight tube fixed inside the mast's radiation shield. This shield permits air to flow freely around...ice damage. This tubing also relieves strain should the buoy drift free from the ice pack in case the pack breaks up. Polyvinyl chloride tubing above the pressure sensor also provides strain relief on the bottom end of...

...sensing cable.

D-cell batteries made of alkaline-manganese dioxide power the Ice Platform battery pack because these yield greater capacity and low-temperature performance than standard retail batteries. The battery pack consists of 16 groups of 12 (nominally 18 volts each) wired in parallel via isolating diodes. This configuration prevents accidental self-discharge of the pack if any battery stick fails. Data acquisition and processing units collect the analog signals from...

...6061-T6 aluminum alloy. This alloy, originally developed by aerospace manufacturers, strengthens the buoy's electronic components' resistance to high-frequency radio waves and protects them from the crushing effects of moving...



Set	Items	Description
S1	467663	IC OR INTEGRATED()CIRCUIT?
S2	494627	(CIRCUIT OR SILICON OR SEMICONDUCT?R OR SEMI()CONDUCT?R OR ELECTRONIC)() (CHIP OR CHIPS OR COMPONENT?)
S3	11690	SMD OR SURFACE()MOUNT?()DEVICE?
S4	4039519	PACKAGE? OR PACK OR PACKS OR PLCC OR QFP
S5	572586	TRAY OR TRAYS OR TUBE OR TUBES
S6	3144263	RECEPTACLE? OR CARRIER?
S7	1349237	CONTAINER? OR BAG OR BAGS
S8	302428	ELECTROSTATIC? OR STATIC? OR ANTISTATIC? OR ESD OR ESC
S9	9936	DESSICAT? OR DESSICANT? OR DESICCAT? OR DESICCANT?
S10	632	DRIBOX OR DRI()BOX OR DRYBOX OR DRY()BOX OR DRIPACK OR DRI- ()PACK OR DRYPACK OR DRY()PACK OR DRIPAK OR DRI()PAK OR DRYPAK OR DRY()PAK
S11	4534	(MOISTURE OR HUMIDITY)() (PROOF OR ABSORB? OR ADSORB? OR AB- SORP? OR ADSORP?)
S12	6227	MONTMORILLONITE OR SILICA()GEL OR MOLECULAR()SIEVE?
S13	4648	CALCIUM() (OXIDE OR SULFATE) OR ACTIVATE?()ALUMIN? OR ALUMI- N?()SILICA?
S14	879	(HUMIDITY OR MOISTURE)() (INDICAT?R? OR MONITOR?) OR HUMITE- CT? OR COBALT()CHLORIDE
S15	1774	POLY() (STYRENE OR PROPYLENE OR VINYL OR AMIDE)
S16	378458	POLYSTYRENE OR POLYPROPYLENE OR POLYMER OR POLYVINYL OR PO- LYAMIDE
S17	2099715	ELASTOMER OR PLASTIC? ?
S18	24786	S1:S3(10N)S4:S7
S19	61	S18 AND S8 AND S9:S13
S20	5	S19 AND S14
S21	39	S19 AND S15:S17
S22	2711	S18 AND S15:S17(10N)S4:S7
S23	319	S22 AND S8:S14
S24	25	S23 AND (S19 OR S39)
S25	25	S23 AND (S29 OR S21)
S26	25	S23 AND (S19 OR S21)
S27	28	S20 OR S24:S26
S28	22	RD (unique items)
S29	20	S28 AND PY<2003

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t 29/5,k/3,4,6,7,9,11

29/5,K/3 (Item 3 from file: 16)  
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07379217 Supplier Number: 60048603 (USE FORMAT 7 FOR FULLTEXT)  
**Logic IC Market & Packages .**  
SMT Trends, pl  
Sept, 1998  
ISSN: 0890-7900  
Language: English Record Type: Fulltext  
Document Type: Newsletter; Trade  
Word Count: 26168  
PUBLISHER NAME: New Insights  
INDUSTRY NAMES: BUSN (Any type of business); ELEC (Electronics)

(USE FORMAT 7 FOR FULLTEXT)  
**Logic IC Market & Packages .**  
TEXT:

A friend called us up and asked what was going on in the logic IC markets. Specifically, our friend asked, what **packages** are going to be used and how many pins will these packages have.?  
... electronic product design is at the place where it has to push upstream, toward the IC itself. The **IC package** is the printed circuit board of the future. These "systems" on a chip will then...ADC, and it isn't a low impedance line, it could cause considerable clock jitter. **Static** timing analysis (provided in the Synopsys toolset) is used to find such problems.

From a...with CMOS VLSI chips, he said.

Another significant breakthrough is the advent of high performance **plastic** fiber. Graded-index fibers made from per-fluorinated polymers have realized a 200-times improvement in bandwidth loss over previous **plastic** -fiber technology and could cut interconnect costs by a factor of 10, Husain said. The...been complicated by semiconductor advances such as increasing bus widths, faster clock speeds and diminishing **IC package** size.

Solving the Connection Problem As chip designers **pack** more functionality into ICs, spacings, sometimes as tight as 0.65 or 0.5 mm...a way to probe three or eight signals on 0.5 and 0.65 mm **IC packages** . The adapter features compressible "conductors" that are inserted into the spaces between the IC pins...the die itself. Additional products are expected to appear later in National's new Micro- **SMD package** . National's LMC6035IBP is a general purpose dual op amp optimized for low power applications...

...to others, but no deals have yet been reached. In addition to op amps, other **IC** categories expected to follow in National's Micro- **SMD package** include regulators, timers, A/D converters, temperature sensors and comparators.

Fujitsu Trims Relay Package by...plane expansion mismatch between the substrate and silicon chips. Organic substrates, such as FR-4, **polyamide** and flexible polyester, are used for special assembly applications.

Chips Process development required mounting and...competitive solutions to this unheralded challenge.

Second is the tension between ultrafine-pitch quad flat **packs** (QFPs) and ball grid array (EGA) **packages** . Approximately 7 billion **plastic** OFPs will be placed in 1995, yet ultrafine-pitch (0.3 to 0.4 mm... Currently, a turret style chipshooter can place about 250 chips/sq. ft/hr. in floor.

Plastic quad flat packs (PQFPs) are clearly dominating the market for IC (integrated circuit) packaging, with a total of approximately seven billion used in 1995. At higher lead counts...

...can be defined.

A further advantage of multichip modules is that since they combine several semiconductor chips in one package, they allow the integration of several chip processing technologies into one circuit package. For example...

...to 70 mm wide tape consists of two or three layers of copper, adhesive, or plastic. The tape has a series of holes, or windows; onto each window is attached an...as increased I/O.

Chip on Board (COB) is the Emperor's New Clothes of IC packaging - it's no package at all. The IC die is placed directly onto the board substrate during assembly of the circuit.

COB is...

...COB has been the reluctance of chip manufacturers to ship ICs out the door without packages. Packages provide isolation and protection for the ICs, and IC manufacturers make money on the packages.

Test and inspection of COB present problems associated with the lack of package leads, the...

...standard EIA 583. This standard relates to the problem of damage caused to SMDs from moisture adsorbed during shipping and storage. Moisture can cause the IC to crack or otherwise deteriorate in integrity or performance. The EIA proposal recommends the use of moisture adsorbing desiccant packets, moisture sensors, and special packing materials.

Wave soldering is the general approach to through...

...than vapor phase due to these advantages.

The heat management problem poses rigorous challenges to integrated circuit package designers. Smaller, more powerful, denser integrated circuits make the problem a packaging problem as we enter the submicron era in microelectronic.

Cooling...

...has generated the most acceptance among SMT designers through 1991. The J-bend, or SOJ, package has leads which bend down and under the IC, saving precious board space and leading to a sturdy lead connection. The alternative gull-wing SO has leads which extend away from the IC, allowing easier inspection and better thermal dissipation for the packaged unit.

The need for higher pin counts in ICs drives packaging innovation. The DIP package...

...board and multichip module level.

The delays associated with electrical transmission between ICs and through IC packages are becoming more significant. Further improvements at the high end will likely require optical solutions...

...and area required for a specific logic function.

Many future semiconductor systems will integrate several semiconductor chips into one package, allowing the combination of several chip processing technologies into one circuit package. Systems involving digital...COB has been the reluctance of chip manufacturers to ship ICs out the door without packages. Packages provide isolation and protection for the ICs and IC manufacturers make money on the packages.

Test and inspection of COB present problems associated with the lack

of package leads, the...usually with a minimum thickness of 10 microns. Preferred materials must exhibit low dielectrics, low **moisture absorption**, planarizing capabilities, and high thermal stability to accommodate subsequent processing.

Traditionally, morganic materials have been...

...cracks and discontinuities. Polymers bring certain advantages with them when used as dielectrics in advanced **packages**. Although no one commercial **polymer** is currently able to meet all requirements, polyimides have received a great deal of...melting range are favorable to the wave soldering process. For single sided circuit boards, the **plastic** melting range of 60/40 alloy helps the solder bridge across larger holes with small...the process occur over the course of an entire day with assured solvent evaporation and **moisture absorption**, etc. Would it not be more sensible to try to produce a solderpaste which will...6

Units(M) 466.9 648.2 1261.4

Year 1997 1999 2003

World Logic IC Market

By **Package** Type

1997-2003

Units (M)

SO 140.1 157.5 201.1

QFP 116.7...

...263.0

Total 466.9 648.3 1261.4

Year 1997 1999 2003

World Logic IC Market By **Package** Type

1996-2003

Units (M)

8 - 32 70.0 78.8 100.6

32 - 132...

19980901

29/5,K/4 (Item 4 from file: 16)

DIALOG(R)File 16:Gale Group PROMT(R)

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03205278 Supplier Number: 44393672 (USE FORMAT 7 FOR FULLTEXT)

**United Desiccants dry pack systems protects SMDs from moisture damage**

Electronic Chemicals News, v9, n2, pN/A

Jan 30, 1994

ISSN: 0886-5671

Language: English Record Type: Fulltext

Document Type: Magazine/Journal; Trade

Word Count: 194

PUBLISHER NAME: Chemical Week Associates

COMPANY NAMES: **United Desiccants**

EVENT NAMES: \*330 (Product information)

GEOGRAPHIC NAMES: \*1USA (United States)

PRODUCT NAMES: \*3295040 (Absorbent Clay Products)

INDUSTRY NAMES: BUSN (Any type of business); CHEM (Chemicals, Plastics and Rubber)

NAICS CODES: 327992 (Ground or Treated Mineral and Earth Manufacturing)

SPECIAL FEATURES: COMPANY

(USE FORMAT 7 FOR FULLTEXT)

**United Desiccants dry pack systems protects SMDs from moisture damage**

TEXT:

United Desiccants is marketing Dry Pack systems, which it says offers moisture protection for SMDs during shipping storage. Dry Pack includes an antistatic barrier bag, a Desi-Pak moisture - adsorbing dessicant, and an SMD - Humitector humidity indicating card. The barrier bag and desiccant protect the sensitive SMDs. The SMD - Humitector, developed specifically for use in the electronics industry, is placed in the sealed container with the Desi-Pak. This humidity indicator card protects electronic components by letting users know when the atmosphere around the electrical device reaches 10, 20, 30 and 40% relative humidity and when the desiccant has reached its moisture adsorption capacity.

... changes from blue to pink if the atmosphere reaches an "unsafe" level or if insufficient desiccant is being used. Humidity indicators also allow each package to be visually inspected, to ensure that the SMD is dry and ready for soldering without decohesion of the plastic from the underside of the leadframe die pad. Desi-Pak desiccants and the SMD-Humitector should be used intandem for best results.

For more information on Dry Pack Electronics applications contact: Don Lawson Humidial, PO Box 610, 465 Mount Vernon Ave., Colton, CA

...  
COMPANY NAMES: United Desiccants  
19940130

29/5,K/6 (Item 2 from file: 148)  
DIALOG(R)File 148:Gale Group Trade & Industry DB  
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13508616 SUPPLIER NUMBER: 75433257 (USE FORMAT 7 OR 9 FOR FULL TEXT)  
Packaging solves "the last centimeter". (Technology Information)  
Israelsohn, Joshua  
EDN, 46, 12, 73  
May 24, 2001  
ISSN: 0012-7515 LANGUAGE: English RECORD TYPE: Fulltext  
WORD COUNT: 3808 LINE COUNT: 00327

INDUSTRY CODES/NAMES: BUSN Any type of business; ELEC Electronics  
DESCRIPTORS: Semiconductor chips--Design and construction  
FILE SEGMENT: TI File 148

... newer TO-273 dispenses with the TO-220's bolt hole and thereby extends the plastic package to near the top of the metal tab. This modification makes room for a larger...

...the MOS switch, the power dissipation derives to first order from the sum of the static (I<sub>sup</sub>.2)R loss and the dynamic losses associated with charging and discharging the...

...not the packaging engineer's only technology that improves small power-MOS performance. Other small plastic package designs minimize their footprints by limiting the extent that leads protrude from the package body...each protect four data lines from 15-kV air-discharge and 8-kV contact-discharge ESD strikes to comply with IEC 61000-4-2 Level 4. Compared with SOT23-6 packaged...

...significantly smaller packages and build on existing equipment, fixturing, and process recipes developed for traditional plastic packaging. This feature reduces the risks and costs associated with developing and qualifying new packages...series inductance  
FEA: finite-element array

FPGA: fine pitch-grid array  
 LLP: leadless lead-frame package  
 NSMD: non-solder mask defined  
 RFIC: radio-frequency integrated circuit  
 SOP: small-outline package  
 SMD : solder mask defined  
 SMT: surface-mount technology  
 TCE: thermal coefficient of expansion

TFP: thin flat...packaging technologies, the higher temperatures challenge a chip maker's ability to ensure that their plastic components meet JEDEC moisture-sensitivity levels 1 and 2 (Reference C and Table A). Based...

...OEMs.

TABLE A--JEDEC MOISTURE-SENSITIVITY LEVELS

JEDEC moisture-sensitivity level	Floor life after opening dry pack
1	Unlimited(*)
2	One year
2A	Four weeks
3	Seven days
4	72 hours

(\*) No dry - pack required

#### REFERENCES

(A.) "What's driving the move to lead-free solder processes," National Semiconductor...

...PCB real estate with chip scale packaging," Xcell Journal, Spring 2001, pg 34.

(5.) "Micro SMD wafer level chip scale package ," Application note 1112, National Semiconductor, November 2000.

(6.) Mescher, Paul, C Scanlan, R Erich, C...

20010524

29/5,K/7 (Item 3 from file: 148)

DIALOG(R)File 148:Gale Group Trade & Industry DB

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12517755 SUPPLIER NUMBER: 64423585 (USE FORMAT 7 OR 9 FOR FULL TEXT)

Minimizing failures in electronic systems by design.(Technology Information)

Lakshminarayanan, V

EDN, 45, 16, 87

August 3, 2000

ISSN: 0012-7515

LANGUAGE: English

RECORD TYPE: Fulltext

WORD COUNT: 7937

LINE COUNT: 00826

INDUSTRY CODES/NAMES: BUSN Any type of business; ELEC Electronics

DESCRIPTORS: Computer peripherals industry--Product development; Testing and measuring equipment industry--Product development; Circuit components --Design and construction; System design--Technique

PRODUCT/INDUSTRY NAMES: 3825200 (Electronic Test & Measure Eqp); 3670000 (Electronic Components)

EVENT CODES/NAMES: 331 Product development

SIC CODES: 3825 Instruments to measure electricity; 3670 Electronic

Components and Accessories  
 NAICS CODES: 334515 Instrument Manufacturing for Measuring and Testing  
 Electricity and Electrical Signals; 3359 Other Electrical Equipment and  
 Component Manufacturing  
 FILE SEGMENT: TI File 148

... because they are sometimes undetectable and lead to field failures  
 of equipment under operating conditions. **Electrostatic** discharge is a  
 common cause of latent damage to electronic components.

You can explain semiconductor...

...during use,

	entry of moisture, flux, or contaminants
Mechanical stress cracks	Differential thermal expansion of <b>plastic</b> encapsulation, metal leads, or die.
Snapping of bond wires in a...	EOS or thermal shock

...in a device

Voids in the device	Chip-substrate attachment failure, thermal overstress
Metallization damage	<b>ESD</b> , corrosion, EOS, temperature
Cracks at the bond-pad-wire junction	EOS
Electromigration	Current flow
Oxide-layer faults	<b>ESD</b> , pinhole due to etching defects or impurities
Crystal defects	Bulk semiconductor-material defects
Layer misalignments...	

...seal

Melting of contacts	EOS (high current)
Damage to coil	EOS (high current)
Damage to <b>plastic</b> case	High temperature during soldering or electrical-stress- induced thermal overstress during use

PC boards...



...The factors that most commonly cause component failure in electronic circuits are EOS (electrical overstress), **ESD** (**electrostatic** discharge) and EMI, and thermal overstress. Each of these categories warrants a thorough discussion.

EOS...short circuit, which further leads to burnouts or charring of the component due to overheating.

#### **ESD AND EMI**

Recently, electronic chip and system designers have taken interest in **ESD** and EMI. The rapid proliferation of small, portable electronic gadgets, switching power supplies, and wireless transmitters and receivers have increased the problem of **ESD** and EMI effects. The miniaturization of electronic components has increased the risk factor for failures from **ESD** and EMI.

**ESD** occurs because of the transfer of electrons by triboelectric charging--for example, the pins of an **IC** sliding down a **tube** charge due to friction. When a charged object or person comes into contact with a...

...can charge that person to a high potential. Higher humidity conditions reduce the effect of **static** charges by providing a discharge path to ground for accumulated charges. Thus, dry air conditions tend to aggravate **ESD** problems, and higher humidity conditions reduce charge accumulation.

For **ESD** to have any effect, a source of **ESD** and a receptor must be present. In general, a source of **ESD** can be manmade or natural, and the receptor can be any component. The action of an **ESD**-induced **electrostatic** field may indirectly affect a component.

#### **ESD REQUIRES A SOURCE AND A RECEPTOR**

**ESD** can cause hardware and software damage in the following electronic systems:

- \* rupture of thin films...

...stress, and

- \* intense electric fields that can cause interference or failure of nearby electronics.

The **ESD** susceptibilities of devices vary depending on their technology. The range of **ESD** threshold varies from 10 to 100V for MOSFETs, 300 to 7000V for bipolar devices, and...

...for CMOS devices. You need to select the appropriate device technology for the end application.

**ESD** prevention should occur at all stages--from manufacturing to the field. Some of the techniques that you can use to mitigate **ESD** problems in electronic circuits include using protective devices at critical points in the circuit; minimizing...

...good pc-board design; selecting components using the right technology with a higher level of **ESD** immunity; and shielding the circuit against **electrostatic** fields. You can use several models of **ESD** to simulate the effects of **ESD** on electronic components and specify thresholds for **ESD** immunity based on end-use requirements. The **ESD** models include the human-body model, the charged-device model, the machine model, and the...

...use the following circuit-design techniques:

- \* Choose components with a high level of immunity to **ESD** and EMI, with considerations for technology, speed, power requirements of your design, bandwidth, rise and...component mounted on it.

- \* Provide a transient-suppressor device and an inrush-current limiter for **ESD**-sensitive devices and at critical points in the circuit.

- \* To suppress noise, slip a ferrite...

...to critical components is to mount the transformer away from sensitive

components. Provision of an **electrostatic** shield between primary and secondary windings can reduce EMI. This shield is a thin copper...

...edges of the board and connecting this trace to ground can help to divert any **ESD** -induced discharge currents that result from human contact to ground. All the precautions you take during production and packing of **ESD** -sensitive components are pointless if operators carelessly handle and assemble boards. For this **ESD** problem, you can provide a guard trace by diverting the energy to ground. Provide a...

...electronic system. The principle of shielding is to absorb or reflect the incident electromagnetic or **electrostatic** field. At low frequencies, absorption of the incident magnetic field is the best method to...as a slot antenna. Unused connectors can charge, so you should keep them covered with **static** -dissipative material when you are not using them. All insulating parts in the cabinet should...

...shields should connect to a 360 (degrees) contact with the cabinet to avoid antenna effects.

**Plastic** materials coated with chemicals such as ammonium salts and amidoamines are available for packing sensitive **electronic components**. **ESD** control through **antistatic** flooring is a useful measure. **Containers** for storing sensitive components are available in the form of conductive **plastic** bins, **trays**, **tubes**, carbon-filled **plastics**, and metal-foil-lined **bags**. These **bags** can be single or multilayered, transparent, or opaque. The opaque **bags** are made of carbon-filled **plastic** and are inexpensive and rugged, which makes them sufficient for most **ESD** -control applications. Metallized- **plastic bags**, which are also transparent and moisture- and heat-resistant, are durable for storing assembled pc...

...and instrument panels. These I/O-shielding materials offer cost-effective shielding against EMI and **ESD**. Sources of electric charge in a production set-up include personnel, clothing, computer terminals, synthetic...

...coverings. Monitoring the handling of components, storage, assembly, testing, and other operations can help prevent **ESD** -induced damage to electronic devices. Conductive foams, **static** -dissipative bags, component storage bins, and tubes are also available for storing sensitive components. Place assembled pc boards in **static** -dissipative bags during storage and shipment. Such containers have a special coating to achieve surface...

...accumulation and potential differences between the pins of the device, which can also lead to **ESD** damage.

#### PREVENT THERMAL-OVERSTRESS FAILURES

Heat is one of the stress factors that affects all....

...dependent. Some of the common reasons for thermal overstress in a device are EOS and **ESD**. Thermal overstress causes damage, such as charring, melting of bond wires, and carbonation of the **plastic** encapsulating material. To prevent such failures, you need to operate a device within its SOA and provide adequate design safeguards against **ESD**, EMI, and thermal overstress. Thermal overstress causes thermal fatigue, thermal runaway, hot spots, and other...physical

changes

High-temperature burn-in

Surface and metallization faults,  
wire-bond defects

Humidity test                      **Moisture absorption** , corrosion,  
chemical reaction

Salt spray                      Resistance to corrosion, simulates  
coastal climate

Moisture resistance              Resistance to...

...die cracks, mismatches in the thermal coefficients of expansion, seal defects, and defects in the **plastic packages** .

Storage at high temperature subjects a component to a higher temperature than in burn-in...

...power or stimuli to the component. The test temperature is around 150 (degrees) C for **plastic** -encapsulated devices and 250 (degrees) C for hermetically sealed devices. Temperature exposure lasts 24 hours...field operation of equipment differ from lab conditions. Components may experience stresses, such as EMI, **ESD** transients, high temperature, corrosive chemical atmosphere, and vibration. Designers often derate the components in terms...

...a high degree of reliability.

TABLE A--DERATING GUIDELINES

Component	Type	Parameter	Derating factor
Capacitors	<b>Plastic</b> dielectric	Voltage rating	0.75
	Ceramic		0.75
	Tantalum electrolytic		0.6
	(solid)	temperature	0.4...0
ICs	Digital	Supply voltage	Within SOA limits
		Junction temperature	100 (degrees) C for <b>plastic</b>
			110 (degrees) C for hermetic
		Speed	0.75
	Analog	Input voltage	Within SOA limits
		Output current	0.8
		Supply voltage	Within SOA limits
		Junction temperature	100 (degrees) C for <b>plastic</b>

			110 (degrees) C for hermetic
		Input voltage	0.75
		Output voltage	0.8
		Power dissipation	0.75
Component	Type	Parameter	Comments
Capacitors	Plastic dielectric	Voltage rating	
	Ceramic		
	Tantalum electrolytic		If effective circuit impedance is > 3 (Omega)/V

(solid...  
...the entire board to fail. Workers should be trained to carefully handle components by observing ESD and handling precautions during all stages of production.

#### EOS DESIGN FAULT

This bipolar-junction transistor...

...4.) Pollino, E, Microelectronic Reliability, Volume II, Artech House, Norwood, MA, 1981.

(5.) Boxleitner, Warren, **Electrostatic** Discharge and Electronic Equipment, IEEE Press, New York.1989.

(6.) Lakshminarayanan, V, "Revisiting environmental stress...

...successful EMC design," RE Design, September 1999, pgs 35 to 47.

(9.) Lakshminarayanan, V, "Minimize ESD -induced failures," Advanced Packaging, August 1999, pgs 36 to 39.

(10.) Bipolar Power Transistor Databook...

20000803

29/5,K/9 (Item 5 from file: 148)

DIALOG(R)File 148:Gale Group Trade & Industry DB

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07806380 SUPPLIER NUMBER: 17001020 (USE FORMAT 7 OR 9 FOR FULL TEXT)

**Electronics firms wrap up success. (packaging of electronic components to be shipped by air freight) (Cover Story)**

Thuermer, Karen

Air Cargo World, v85, n4, p24(5)

April, 1995

DOCUMENT TYPE: Cover Story

ISSN: 0745-5100

LANGUAGE: ENGLISH

RECORD TYPE: FULLTEXT

WORD COUNT: 1844 LINE COUNT: 00143

SPECIAL FEATURES: illustration; photograph

INDUSTRY CODES/NAMES: AERO Aerospace and Defense; TRAN  
Transportation, Distribution and Purchasing  
DESCRIPTORS: Electronic components industry--Packaging; Air freight--  
Safety and security measures; Packaging--Management  
PRODUCT/INDUSTRY NAMES: 3670000 (Electronic Components); 4502000 (Air  
Cargo Service)  
SIC CODES: 3670 Electronic Components and Accessories; 4512 Air  
transportation, scheduled  
FILE SEGMENT: TI File 148

... a sponge. For that reason, Adaptec no longer uses single tarps or  
foam inside the **packages**. "We replaced it with **plastic anti-static**  
**bags** when we started sterilizing our products," she said.

Monica Silvers, international transportation coordinator for Apple...

...To prevent moisture problems, Apple wraps its products in what she  
described as "old fashion **plastic bags**." Inside the **packages**, they  
also use chaplets that draw the moisture away from the product.

Sometimes even the slightest moisture can damage **electronic**  
**components**, particularly **surface mounted devices (SMD)**.  
Manufacturers and **packagers** of these products have reported increased  
product protection from humidity damage by using **Dry Pack** packaging  
manufactured by United **Desiccants**.

The small **moisture - adsorbing desiccants** packets seal moisture  
out, whereas the **humidity indicator** cards lets users know when the  
atmosphere around the electrical device reaches 10, 20, 30 and 40 percent  
relative humidity. The **humidity indicators** also allow each **package** to  
be visually inspected, to insure that the **SMD** is dry and ready for  
soldering without decohesion of the **plastic** from the underside of the  
leadframe die pad.

David Olsson, operations manager for William Wetmore...says. "My  
advice is to minimize the size within the technical constraints," such as  
electro **static** discharge and shock vibration protection.

Olsson recommends keeping the package to 64 inches or less...

19950400

29/5,K/11 (Item 7 from file: 148)  
DIALOG(R)File 148:Gale Group Trade & Industry DB  
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07607126 SUPPLIER NUMBER: 16528996 (USE FORMAT 7 OR 9 FOR FULL TEXT)  
**Motorola deflates device damage.**

Packaging Digest, v31, n12, p74(3)  
Nov, 1994

ISSN: 0030-9117 LANGUAGE: ENGLISH RECORD TYPE: FULLTEXT; ABSTRACT  
WORD COUNT: 1866 LINE COUNT: 00147

ABSTRACT: Tempe, AZ-based Motorola encountered damage problems in shipping  
integrated circuit (IC) chip products for its Commercial Plus Technologies  
Operation. The firm's ICs were becoming more complicated that traditional  
packaging inevitably failed to protect the highly-sensitive products.  
Motorola found the solution in a joint venture project with Air Packaging  
Technologies. The joint effort generated the **Static** Discharge Shielding  
Air Box Reusable, an inflatable bag that protects and immobilizes the chips  
in an air cushion.

SPECIAL FEATURES: illustration; photograph  
COMPANY NAMES: Motorola Inc.--Packaging; Air Packaging Technologies Inc.  
--Products

INDUSTRY CODES/NAMES: CONT Containers and Packaging  
DESCRIPTORS: Semiconductor industry--Packaging; Packaging industry--  
Products  
PRODUCT/INDUSTRY NAMES: 3674126 (IC Memory Chips); 2643900 (Bags NEC)  
SIC CODES: 3674 Semiconductors and related devices; 2670 Misc.  
Converted Paper Products  
FILE SEGMENT: TI File 148

...ABSTRACT: solution in a joint venture project with Air Packaging Technologies. The joint effort generated the **Static** Discharge Shielding Air Box Reusable, an inflatable bag that protects and immobilizes the chips in...

TEXT:

Reusable air **bag** for expensive **integrated circuits** offers improved protection from shock, **ESD** damage and moisture, cutting materials and labor costs 44 percent. Inflatable nylon/LLDPE bags replace

...  
... joint venture effort by both Motorola and the bag's manufacturer, Air Packaging Technologies. Called **Static** Discharge Shielding (SDS) Air Box [R] Reusable, the bag has been used in CPTO's...

...see-through film of the air bag permits instant verification of contents and allows the **humidity indicator** card to be read without opening the package. Bar codes can also be scanned right...

...by 90 percent. Extensive drop tests show that cushion protection exceeds ISTA and ASTM standards.

\* **ESD** protection exceeds current standards, according to several tests conducted by independent testing firms.

\* High moisture...

...with the exception of an open end in which product is inserted along with a **humidity indicator** card from Humidial/United **Desiccants**. An operator applies pressurized air from an inexpensive regulator, supplied by Air Packaging Technologies, to...

...air gap/film/product/ film/air gap/film, is what gives the package its strong **ESD** protection. The air gaps can range anywhere from 1/2 to 1 in. thick, depending on the contents, and the **static** -dissipative bag material relies on nylon to give it a variety of performance characteristics. After ...

...Associates confirmed the combination of the material and the air gaps "provide a very good **ESD** package for essentially all devices under essentially all conditions." In one test, the **package** withstood a 20 kV discharge while containing **integrated circuits** that are rated at 150 v maximum.

In addition to providing cushioning capability and **ESD** protection, the air gap forms a strong moisture barrier. **Desiccant** pouches from Multiform **Desiccants** are also added to the air gap portion of the bag during bag manufacture to...

...either dry air or nitrogen which further restricts moisture vapor transmission and also contributes to **ESD** protection. Moisture barrier tests show a **desiccated** Air Box inflated with dry air to have a moisture vapor transmission rate of 0...

...24 hr at 100 percent relative humidity and 23 deg C.

Before ICs can be **packaged**, they are first placed in an **IC**

carrier , which can take one of three forms-- **plastic trays** , reels or rails, all from multiple suppliers, depending on the type of chip and customer...less complex and more rugged, although these chips too will eventually go in the **air bag** .

In the old packaging process, **IC carriers** were first stacked, strapped with **plastic** strapping material and wrapped in **antistatic** shrink film, from various suppliers. The shrink pack was then placed in metallized barrier bags along with **desiccant** pouches and a **humidity indicator** card. After being vacuum-sealed (which, Duncan points out, makes it difficult for **desiccants** to do their job well), the bags would be placed inside a primary corrugated container...

...sixth empty one for top protection) and placed in .029 paperboard end caps--instead of **plastic** strapping--from Arizona Paper Box and printed in soybean ink with the Motorola logo, an **ESD** warning, and a recycled logo. The end caps, which are hand-formed immediately prior to application, are easier to apply and remove, and are being recycled, which the **plastic** straps weren't. Bar code labels are placed on the end caps with a part...

...as a listing of the standards that the bag passes. Information currently applied by the **static** treatment coater but which in the future will be preprinted includes a date code for **static** -dissipative treatment and international symbols indicating **ESD** and moisture sensitivity.

At the point of use in the customer's plant, bags are...  
...air escapes. The bag's sealed edge is trimmed off, and the operator removes the **IC carriers** . Although Motorola is not currently doing so, it plans to rouse the bags at least...

...is available: Air Box--Air Packaging Technologies, Inc., 25620 Rye Canyon Rd., Valencia, Calif. 91355.

**Humidity indicator** card--Humidial/United **Desiccants** , Box 610, Colton, Calif. 92324.

**Desiccant** pouch--Multiform **Desiccants** , Inc., 960 Busti-at-Niagara, Buffalo, N.Y. 14213.

Paperboard end caps--Arizona Paper Box, P.O. Drawer 1219, Spring Valley, Calif. 91977.

**ESD** testing--Fowler Associates, Inc., 3551 Moore-Duncan Hwy., Moore, S.C. 29369.

Bi-ax nylon rollstock...

...Packaging, 285 Industrial Pkwy. S., Aurora, Ont. L4G 3V8. Canada.

Inner film LLDPE resin--Dow **Plastics** , 2040 Dow Center, Box 1206, Midland, Mich. 48674.

AmeriStar competition--Institute of Packaging Professionals, 481...

19941100

INTERNET ARCHIVE



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Searched for <http://www.peripheralconfigurator.com/configurator2/glossaryall.asp>

10 Results

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					<u>Aug 05, 2001</u>	<u>Aug 05, 2002</u>	
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						<u>Dec 05, 2002</u>	

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# TECHNICAL GLOSSARY

From A to Z, we created a vast list of Glossary terms to assist you. We have given you two ways to search you can either go directly to the term, using the drop down list or you can scroll through the entire glossary.

Find it!

Submit

XMS-EXTENDED MEMORY SPECIFICATION

Get the Definition

We have listed our entire glossary below for easy navigation.

**(AGP)-ACCELERATED GRAPHICS PORT**

High speed graphics. Data shifts directly from the graphics controller and the computer memory, bypassing the cache in video memory.

**ACCESS TIME**

The average time period, for RAM, between a query for information and its completed access.

**AMRAY**

Equipment used to gauge crucial information from an area on a semiconductor component at various levels of operations through the use of a Scanning Electron Microscope(SEM).

**ANSI-(AMERICAN NATIONAL STANDARDS INSTITUTE)**

The United States organization responsible for setting information technology standards.

**ARRAY**

This is a large rectangular area in the center of a semiconductor component where memory is stored. Memory is stored in cells at each intersection of columns and rows, each of which holds a bit.

**ASCII(American Standard Code for Information Interchange)**

A method of encoding text as binary values. The ASCII system requires nearly 256 combinations of 8-bit binary numbers to support every possible keystroke from the keyboard.

**ASIC-(APPLICATION-SPECIFIC INTEGRATED CIRCUIT)**

These chips are created for a specific application rather than common use. Integrated-circuit chips are typically used in video boards and modems.

**ASYNCHRONOUS**

A process involving numerous tasks being performed independently in a system.

**ATA-(AT ATTACHMENT)**

A specification that integrates the drive control electronics interface. AT refers to the IBM PC/AT personal computer and its bus architecture.

**AUTO PRECHARGE**

A DRAM feature that enables the circuitry in a memory chip to automatically close a page at the end of a request from the processor for a single block of data.

**BACKSIDE BUS(BSB)**

BSB is the path in which data flows between the computer processing unit and the level 2 cache.

**Bandwidth**

The capacity to move data on an electronic line such as a bus or a channel. In short, the amount of data moved relative to a specific time frame. It is expressed in bits, bytes, or Hertz (cycles) per second.

**Bank (I gical memory bank)**

A collection of memory slots in a computer which work together as a single unit. A bank cannot be partially filled and must be filled with like modules (same size, speed and type).

**BANK SCHEMA**

A procedure in which memory configuration is diagramed. Independent sockets are represented by rows and banks are illustrated by columns.

**BASE RAMBUS**

The beginning of Rambus technology, shipped first in 1995.

**BEDO-(BURST EDO)**

Similar to EDO DRAM, Burst EDO cycles are assembled in bursts of four. Bus speeds of Burst EDO range from 40mhz to FPM or EDO DRAM.

**Binary**

A method of encoding numbers as a series of bits. The binary number system, also referred to as base 2, uses combinations of only two digits- 1 and 0.

**BIOS-(BASIC INPUT/OUTPUT SYSTEM**

A set of low level RAMBUS that allow a computer's application programs and operating systems to read characters from the keyboard, output characters to printers, and interact with the hardware in other ways.

**Bit**

A binary digit- the smallest unit of information a computer system can process. It can have a value of only 1 or 0 (off or on). Single bits are too small to be of much use and are usually classified in groups such as bytes of binary words.

**BLOCK**

A block is a physical unit of data in a logical record that is expressed in bytes.

**BLOCK DIAGRAM**

A diagram of the system dealing with important functions and interconnections between them.

**Brand- n-Brand Memory**

(See original memory).

**BUFFER**

Shared information from devices operating at different speeds are held in the buffer. This buffer enables a device to function without delays from other mechanisms.

**BUFFERED MEMORY**

A module that houses buffers, which are used to help control the signals the memory chips receive. In addition, they allow the module to include more memory chips. Buffered and non-buffered memory cannot be combined.

**BURN-IN**

Using a high voltage and temperature to test an integrated circuit. This procedure will find those chips that tend to fail early during actual use. Chips that pass tend to have a

longer life expectancy than required for regular use.

**BURST EDO RAM**

EDO Memory that processes four memory addresses in one burst. Speeds of the Bus may range from 50mhz to 66mhz.

**BURST MODE**

A high speed transmission of a series of addresses that occur when the processor asks for a single address.

**Bus**

The central communication avenue in a PCs system board. If normally consists of a set of parallel wires or signal traces that connect the CPU, the memory, all input/output devices, and peripherals.

**Bus cycle**

A single transaction between system memory and the CPU.

**Byte**

A unit of information made up of 8 bits. The byte is the key component of computer processing; most computer component specifications are measured in bytes or multiples thereof (such as kilobytes or megabytes).

**Cache**

A type of memory which is used to store frequently used instructions and data. Cache memories are used to increase the performance of computing systems by holding these frequently used instructions and data closer (in a speed-related context) to their final destination.

**CAPACITANCE**

The characteristic of a circuit element that enables it to store an electrical charge.

**CAS LATENCY**

The ratio between column access time and clock cycle time.

**CAS-(COLUMN ADDRESS STROBE)**

A memory chip signal that connects the column address of a specific location in a row-column configuration.

**CE**

The International symbol on all electrical equipment stating that it was certified per EN50082-2 (Immunity) and EM5501A (emissions).

**CHECK BITS**

Additional data bits that a module supplies to support ECC.

**CHIP-SCALE PACKAGE**

Thin chip package in which electrical connections are usually through a ball grid array. Used in RDRAM and flash memory.

**CHIPSET**

The computer processing unit is supported by the chipset, a set of microchips which contain several controllers, determining how data travels between components and the processor.

**CHMOS**

Complementary High-density Metal Oxide Semiconductor,

**CISC-(COMPLEX INSTRUCTION SET COMPUTING**

A design logic in which chips combine multi-step instructions into one command. CISC is usually associated with microprocessors.

**CLOCK RATE**

The number of pulses discharged by a computer's clock in a one second interval. In a synchronous computer, clock rate establishes the time period in which logical or arithmetic gating occurs.

**COB-(CHIP ON BOARD)**

A technique or system in which semiconductor dice are connected to a PC board with bonded wires or solder balls.

**COLUMN**

A portion of the memory array whereby information is stored at the junction of a column and a row.

**COMPACT FLASH**

Removable storage cards that are efficient in terms of weight, size, and durability. In addition, they utilize small amounts of voltage and retain information when the power is off. Often used in digital cameras, printers, and handheld computers.

**Comp site Memory**

A term used by Apple Computer to describe modules which use many low-density memory (4 Megabit) chips.

**CONCURRENT RAMBUS**

The second generation of Rambus technology.

**CONTROLLER**

A major component of a computer that interprets and performs program commands.

**COPLANARITY**

In terms of a semiconductor package, coplanarity refers to the condition of leads between two parallel planes.

**CPU**

Central Processing Unit. The "brains" of a computer system. A CPU is an integrated circuit which processes the bulk of the data and software instructions in a computer system. It is commonly referred to as "the processor" in a computer system.

**CRC-(CYCLICAL REDUNDANCY CHECK**

A mathematical method to discover errors involving long runs of information with a greater degree of accuracy.

**Credit Card Memory**

A type of memory module (much like a PCMCIA card) named for its size. Credit card modules are commonly used in notebooks and other portable computing devices.

**CRIMM-(CONTINUITY RIMM)**

Direct Rambus memory in which the module does not contain any memory chips. Used to fill unused RIMM sockets to allow for an uninterrupted pathway for a signal.

**DAMPING**

The deterioration of oscillations as a result of the resistance in resonant circuits.

**DATA OUT**

The pathway that transmits the information from the RAM.

**DATE CODE**

A mark placed on PCBs and DRAM indicating the date that the product was manufactured.

**DDR (Double Data Rate) r SDRAM II**

The next generation of SDRAM. DDR is based on the same design as SDRAM, but its speed capabilities are enhanced. DDR allows data to be read on both the rising and the falling edge of the clock cycle, delivering twice the bandwidth of standard SDRAMs. DDR, in effect, doubles memory speed without increasing the clock frequency.

**DIE**

Die refers to one unpackaged part of thousands of tiny electronic parts forming the internal circuitry of a semiconductor component. It is also known as an integrated circuit or chip.

**DIE PICK-UP TOOL**

The tool on the machine that picks up the semiconductor component or part and places it on the leadframe.

**DIE SIZE**

Die size is the physical measurements of the die.

**DIELECTRIC**

Components used in semiconductor processing that, when voltage is applied, conduct no current. Examples of dielectrics include silicon dioxide and silicon nitride.

**DIELECTRIC DEPOSITION**

When a layer of deposited oxide is applied to separate (isolate) two metals in a double-level metal process. Must be accomplished in a way that prevents hillock formation on the top level.

**DIMM**

Dual In-Line Memory Module. A type of memory with contacts along one edge of a printed circuit board. A DIMM is much like a SIMM except the contacts on either side of a DIMM are not electrically connected like they are on a SIMM (pin 1 on the back and pin 1 on the front do not make the same connection). See also: memory module, SIMM.

**DIP (Dual In-line Package)**

A form of DRAM component packaging. DIPs are installed either in sockets or permanently soldered into a hole extending into the surface of the printed circuit board.

**DIRECT ADDRESS**

A memory address contained as part of the instruction.

**DIRECT MEMORY ACCESS**

A computer characteristic that enables peripheral systems to access memory for read and write operations, yet not affect the central processor of a computer.

**DIRECT RAMBUS**

Rambus technology's third generation, which offers a completely new DRAM architecture for high-performance PCs.

**DISTRIBUTED PROCESSING**

A process which frees the CPU of the details of block transfers by utilizing intelligent input/output controllers and direct memory access.

**DRAM**

Dynamic Random Access Memory. The most common form of primary storage used in computer systems. This type of memory must be 'refreshed' periodically to maintain the stored data (hence the term dynamic). The data in DRAM is lost when the power is removed from the circuit; therefore, the data in DRAM must be moved to a secondary storage device such as a hard drive floppy drive.

**DRIVER BOARD**

A PCB that transmits signals between the interface board of the oven and the DUT board. For each oven slot, there is a corresponding driver board situated in the rear of the oven.

**DRY PACK**

A method for preparing product to be shipped. It involves placing product, a clay desiccant, and an HIC (humidity indicator card) into a vacuum-sealed moisture vapor barrier bag.

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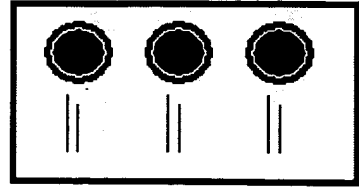
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- ▶ Solutions
- ▶ Technologies & Trends
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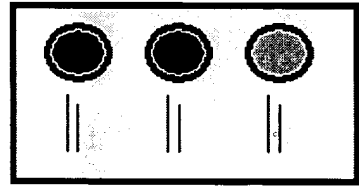
## Integrated Circuit (IC) Storage and Handling: Damage Prevention

### General Device Storage: Safe Environmental Conditions: *Short term*

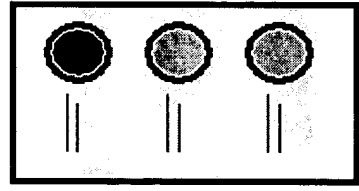
- Short-term storage:
  - Short term storage is considered to be up to 1 year.
  - Customers need to follow established handling/storage practices so as to ensure reliable manufacture of their product.
- Moisture related failures:
  - Affected devices are packed in Moisture Barrier Bags (MBBs) with a desiccant and Humidity Indicator Card (HIC).
  - Packaging guarantees a minimum shelf life of 12 months at 40°C/90% relative humidity (RH), provided that bag integrity is not violated.
  - After the 12 month period has expired, the user must examine the HIC to see if the moisture content is low enough for safe usage.
  - If HIC indicates that the allowable moisture level has been exceeded, then devices must be baked to remove excess moisture prior to the soldering process.
  - For more information, see [device moisture sensitivities](#).



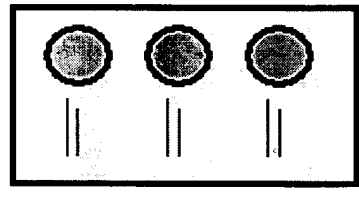
**Initial Condition**



**Warning**



**Replace Desiccant**



**Pre-Bake Required**



- A pre-solder bake will be required if:
  - MBBs are damaged during short term storage.
  - Devices are NOT soldered within the time stipulated on MBB label.
  - Devices have been stored for many years and desiccant has expired.
- Conditions for bake:
  - Low Temperature Bake:
    - 192 hours at 40°C +5°C/-0°C and <5% relative humidity (RH)
    - Standard bake which guarantees stability of tube/tape and reel dimensions
  - High Temperature Bake:
    - 24 hours at 125°C +/-5°C
    - For devices out of packaging or devices supplied in high temperature trays

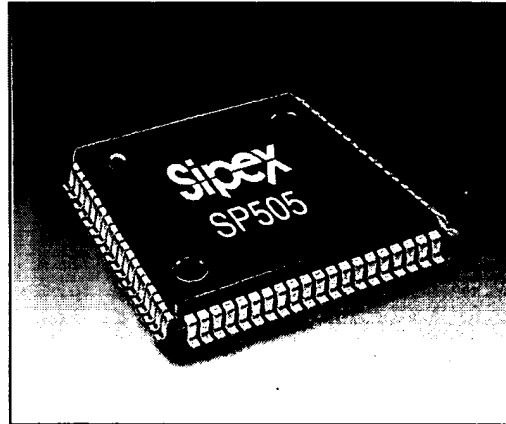
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## WAN Multi-Mode Serial Transceiver

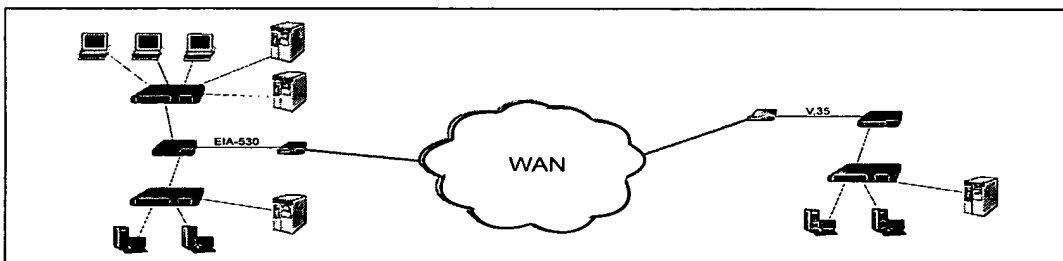
- +5V Only Operation
- Seven (7) Drivers and Seven (7) Receivers
- Driver and Receiver Tri-state Control
- Internal Transceiver Termination Resistors for V.11 and V.35 Protocols
- Loopback Self-Test Mode
- Software Selectable Protocol Selection
- Interface Modes Supported:
  - ✓ RS-232 (V.28)      ✓ X.21/RS-422 (V.11)
  - ✓ EIA-530 (V.10 & V.11)    ✓ EIA-530A (V.10 & V.11)
  - ✓ RS-449 (V.10 & V.11)    ✓ V.35 (V.35 & V.28)
  - ✓ V.36 (V.10 & V.11)    ✓ RS-485 (un-terminated V.11)
- Improved ESD Tolerance for Analog I/Os
- High Differential Transmission Rates
  - ➔ SP505A - 10Mbps
  - ➔ SP505B - over 16Mbps
- Compliant to NET1/2 and TBR2 Physical Layer Requirements  
(TUV Test Report NET2/052101/98)  
(TUV Test Report CTR2/052101/98)



### DESCRIPTION...

The **SP505** is a monolithic device that supports eight (8) popular serial interface standards for DTE to DCE connectivity. The **SP505** is fabricated using a low power BiCMOS process technology, and incorporates a Sipex patented (5,306,954) charge pump allowing +5V only operation. Seven (7) drivers and seven (7) receivers can be configured via software for any of the above interface modes at any time. The **SP505** requires no additional external components for compliant operation for all of the eight (8) modes of operation. All necessary termination is integrated within the **SP505** and is switchable when V.35 drivers, V.35 receivers, and V.11 receivers are used. The **SP505** can operate as either a DTE or DCE.

Additional features with the **SP505** include internal loopback that can be initiated in either single-ended or differential modes. While in loopback mode, driver outputs are internally connected to receiver inputs creating an internal signal path convenient for diagnostic testing. This eliminates the need for an external loopback plug. The **SP505** also includes a latch enable pin with the driver and receiver address decoder. Tri-state ability for the driver and receiver outputs is controlled by supplying a 4-bit word into the address decoder. Seven (7) drivers and one (1) receiver in the **SP505** include separate enable pins for added convenience. The **SP505** is ideal for WAN serial ports in networking equipment such as routers, switches, DSU/CSU's, and other access devices.



## ABSOLUTE MAXIMUM RATINGS

These are stress ratings only and functional operation of the device at these ratings or any other above those indicated in the operation sections of the specifications below is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

$V_{CC}$ .....	+7V
Input Voltages:	
Logic.....	-0.3V to ( $V_{CC}+0.5V$ )
Drivers.....	-0.3V to ( $V_{CC}+0.5V$ )
Receivers.....	$\pm 15.5V$
Output Voltages:	
Logic.....	-0.3V to ( $V_{CC}+0.5V$ )
Drivers.....	$\pm 15V$
Receivers.....	-0.3V to ( $V_{CC}+0.5V$ )
Storage Temperature.....	-65°C to +150°C
Power Dissipation.....	2000mW
Package Derating:	
$\theta_{JA}$ .....	46°C/W
$\theta_{JC}$ .....	16°C/W

## STORAGE CONSIDERATIONS

Due to the relatively large package size of the 80-pin quad flat-pack, storage in a low humidity environment is preferred. Large high density plastic packages are moisture sensitive and should be stored in Dry Vapor Barrier Bags. Prior to usage, the parts should remain bagged and stored below 40°C and 60%RH. If the parts are removed from the bag, they should be used within 48 hours or stored in an environment at or below 20%RH. If the above conditions cannot be followed, the parts should be baked for four hours at 125°C in order to remove moisture prior to soldering. Sipex ships the 80-pin QFP in Dry Vapor Barrier Bags with a humidity indicator card and desiccant pack. The humidity indicator should be below 30%RH.

## SPECIFICATIONS

$T_A = +25^\circ\text{C}$  and  $V_{CC} = +4.75V$  to  $+5.25V$  unless otherwise noted.

	MIN.	TYP.	MAX.	UNITS	CONDITIONS
<b>LOGIC INPUTS</b>					
$V_{IL}$ $V_{IH}$	2.0		0.8	Volts Volts	
<b>LOGIC OUTPUTS</b>					
$V_{OL}$ $V_{OH}$	2.4		0.4	Volts Volts	$I_{OUT} = -3.2\text{mA}$ $I_{OUT} = 1.0\text{mA}$
<b>V.28 DRIVER</b>					
<b>DC Parameters</b>					
Outputs					
Open Circuit Voltage			$\pm 15$	Volts	per Figure 1
Loaded Voltage	$\pm 5.0$		$\pm 15$	Volts	per Figure 2
Short-Circuit Current			$\pm 100$	mA	per Figure 4
Power-Off Impedance	300			$\Omega$	per Figure 5
<b>AC Parameters</b>					
Outputs					
Transition Time			1.5	$\mu\text{s}$	per Figure 6; +3V to -3V
Instantaneous Slew Rate			30	V/ $\mu\text{s}$	per Figure 3
Propagation Delay					
$t_{PHL}$	0.5	1	5	$\mu\text{s}$	
$t_{PLH}$	0.5	1	5	$\mu\text{s}$	
Max. Transmission Rate	120	230		kbps	
<b>V.28 RECEIVER</b>					
<b>DC Parameters</b>					
Inputs					
Input Impedance	3		7	k $\Omega$	per Figure 7
Open-Circuit Bias			+2.0	Volts	per Figure 8
HIGH Threshold		1.7	3.0	Volts	
LOW Threshold	0.8	1.2		Volts	
<b>AC Parameters</b>					
Propagation Delay					
$t_{PHL}$	50	100	500	ns	
$t_{PLH}$	50	100	500	ns	

## ⑫ 公開特許公報(A)

昭62-158042

⑤ Int. Cl.<sup>4</sup>B 32 B 27/18  
27/08

識別記号

庁内整理番号

J-7112-4F  
7112-4F

④ 公開 昭和62年(1987)7月14日

審査請求 未請求 発明の数 1 (全3頁)

⑬ 発明の名称 ヒートシール容易な制電コートフィルム

⑰ 特 願 昭61-281

⑱ 出 願 昭61(1986)1月7日

⑭ 発 明 者 服 部 英 二 鈴鹿市平田中町1番1号 旭化成工業株式会社内  
 ⑯ 出 願 人 旭化成工業株式会社 大阪市北区堂島浜1丁目2番6号  
 ⑰ 代 理 人 弁理士 野崎 鏝也

## 明 細 書

## 1. 発明の名称

ヒートシール容易な制電コートフィルム

## 2. 特許請求の範囲

1 プラスチックフィルムのヒートシールできる面Aに、カーボンブラックを含み透視できる導電層Bと、ウレタンプレポリマー10～50%を含む二次転移温度90℃以下のアクリル樹脂層Cとを、Aに対しB、Cの順にコートして硬化した上記コート面でヒートシール容易な制電コートフィルム。

2 導電層Bがメッシュ状に塗布されている特許請求の範囲第一項記載の制電コートフィルム。

## 3. 発明の詳細な説明

(産業上の利用分野)

本発明は静電気障害を受けやすい物品の包装に使用する制電コートフィルムに関するものであって、特に制電コート面でヒートシールして袋などの形状にして使用するのに適したフィルムに関する。

(従来の技術)

通常のプラスチックフィルムはその表面抵抗値(JIS K6911に準拠した測定値をいう。以下同じ)が $10^{14}\Omega$ 以上であり、フィルム自体も容易に帯電し、又、そのフィルムと接触し摩擦を受ける他の物体を強く帯電させるので、静電気障害を受け易い物品を包装するためには帯電防止処理することが必要であった。本発明者等は、先に表面抵抗が低く、かつ透視可能な帯電防止プラスチックフィルムを完成し出願した(特開昭60-214945号)。

更に、前記の帯電防止フィルムを用いて、静電気障害を受け易い物品の保護に最も適した包装体について研究を重ねた結果、表面抵抗が低い面が、包装体の外側ではなく、被包装物の側にあることが、被包装物保護のために特に有利であることを見出し、これにもとずき、静電気障害を受け易い物品の保護に有効な袋の構造についての発明を完成し、特願昭59-199975号を出願した。

しかし、表面抵抗が低いフィルム面を得るために、カーボンブラックを導電材料とする透視可能

DERWENT-ACC-NO: 1987-232702

DERWENT-WEEK: 198733

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TITLE: Readily heat-sealable plastic film - having  
charge-controlling coating contg. carbon black, and  
acrylic! resin layer contg. urethane prepolymer

PATENT-ASSIGNEE: ASAHI CHEM IND CO LTD[ASAH]

PRIORITY-DATA: 1986JP-0000281 (January 7, 1986)

PATENT-FAMILY:	PUB-NO	PUB-DATE	LANGUAGE	PAGES	MAIN-IPC
	JP 62158042 A	July 14, 1987	N/A	003	N/A

APPLICATION-DATA:	PUB-NO	APPL-DESCRIPTOR	APPL-NO	APPL-DATE
	JP 62158042A	N/A	1986JP-0000281	January 7, 1986

INT-CL (IPC): B32B027/18

ABSTRACTED-PUB-NO: JP 62158042A

BASIC-ABSTRACT:

Film is composed of a plastic film having a heat sealable surface, an electroconductive layer contg. carbon black and capable of being seen through, and an acrylic resin layer contg. 10-50 % urethane prepolymer and having a sec. transition temp. below 90 deg.C. The layers are coated and cured in this order on the heat sealable surface of the plastic film. Specifically the electroconductive layer is a mesh-form coat.

Plastic film is polyethylene, EVA, polypropylene, 1,2-polybutadiene, etc. A polyester film coated with an ethylene-vinyl acetate copolymer is exemplified. A pref. urethane prepolymer is a two-liq. type consisting of a polyol and a polyisocyanate or a moisture-curable liquid type. A pref. electroconductive layer is formed of partially-saponified EVA copolymer contg. carbon black.

USE/ADVANTAGE - For packaging of articles which are liable to suffer electrostatic problems i.e. IC's. The film can be easily formed into a bag. The mesh-form electroconductive layer contributes to the high heat-sealing property. Contents of the bag can be seen.

CHOSEN-DRAWING: Dwg.0/0

TITLE-TERMS: READY HEAT SEAL PLASTIC FILM CHARGE CONTROL COATING CONTAIN CARBON  
BLACK POLYACRYLIC RESIN LAYER CONTAIN URETHANE PREPOLYMER

ADDL-INDEXING-TERMS:  
POLYETHYLENE@ POLYVINYL ACETATE POLYPROPYLENE@ POLYBUTADIENE  
POLYESTER

DERWENT-CLASS: A14 A25 A85 A94 P73

CPI-CODES: A08-M09A; A08-R03; A09-A03; A10-E24; A12-P01A; A12-S06C;

UNLINKED-DERWENT-REGISTRY-NUMBERS: 5085U

POLYMER-MULTIPUNCH-CODES-AND-KEY-SERIALS:

Key Serials: 0218 0226 0231 0241 3155 0486 0487 0789 3185 1758 2007 2008 2020  
2021 2022 2198 2217 2274 2278 2437 2493 2513 2551 2553 2595 3254 2667 2726 2743  
2774 2776 0239 0248 1073 1093 1291  
Multipunch Codes: 014 02& 034 04- 040 041 046 047 066 067 074 081 150 209 231  
244 245 250 27& 307 308 310 318 321 326 359 373 381 431 435 443 473 477 50& 506  
509 511 516 523 56& 58- 597 600 604 608 623 627 688 722 723 724 014 02& 034 04-  
040 041 046 047 050 066 067 074 081 150 209 231 244 245 250 27& 307 308 310 318  
321 326 359 373 381 431 435 443 473 477 50& 506 509 511 516 523 56& 58- 597 600  
604 608 623 627 688 722 723 724 014 02& 034 04- 040 041 046 047 066 067 074 081  
117 118 122 150 209 231 244 245 250 27& 307 308 310 318 321 326 359 373 381 431  
435 443 473 477 50& 506 509 511 516 523 56& 58- 597 600 604 608 623 627 688 722  
723 724 014 02& 034 04- 040 041 046 047 066 067 074 081 143 144 150 209 231 244  
245 250 27& 307 308 310 318 321 326 359 373 381 431 435 443 473 477 50& 506 509  
511 516 523 56& 58- 597 600 604 608 623 627 688 722 723 724

SECONDARY-ACC-NO:

CPI Secondary Accession Numbers: C1987-098374

(19)日本国特許庁 (J P)

(12) 公開特許公報 (A)

(11)特許出願公開番号

特開平4-367457

(43)公開日 平成4年(1992)12月18日

(51)Int.Cl.<sup>5</sup>

B 6 5 D 73/02

識別記号

庁内整理番号

F I

技術表示箇所

J 7191-3E

M 7191-3E

審査請求 未請求 請求項の数2(全 7 頁)

(21)出願番号 特願平3-155383

(22)出願日 平成3年(1991)5月31日

(71)出願人 000190116

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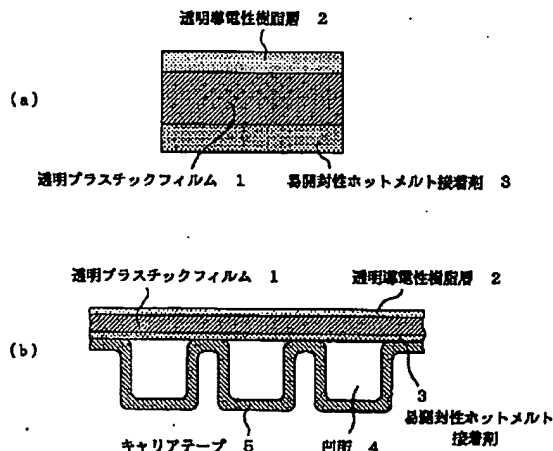
(74)代理人 弁理士 山本 亮一 (外1名)

(54)【発明の名称】 カバーテープフィルムおよびこれを使用した実装部品包装体

(57)【要約】 (修正有)

【目的】 高温高温下に長期間さらしても表面抵抗が上昇することなく、透明性に優れ、スティッキングを起こさず、長期間清掃する必要のない実装部品包装体を提供する。

【構成】 透明プラスチックフィルム1の表面に、平均粒径が0.3  $\mu$ m以下の酸化スズ化合物および/または酸化インジウム化合物の微粉末とバインダー樹脂とから成る透明導電性樹脂層2を設け、裏面にホットメルト接着剤3を設けた透明性複合カバーテープフィルムと、帯電防止または導電性の樹脂シートに実装部品を収納する凹部4を連続的に設けたキャリアテープ5とよりなり、該ホットメルト接着剤層で該キャリアテープが易開封性に熱シールされている。



DERWENT-ACC-NO: 1993-041302

DERWENT-WEEK: 199305

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TITLE: Cover tape film for package for mounting (e.g. electronic) parts - comprising hot melt adhesive backing, transparent plastic film and conductive layer of binder contg. tin oxide and/or indium oxide fine particles

PATENT-ASSIGNEE: SHINETSU POLYMER CO[SHPL]

PRIORITY-DATA: 1991JP-0155383 (May 31, 1991)

PATENT-FAMILY:

PUB-NO	PUB-DATE	LANGUAGE	PAGES	MAIN-IPC
JP 04367457 A	December 18, 1992	N/A	004	B65D 073/02

APPLICATION-DATA:

PUB-NO	APPL-DESCRIPTOR	APPL-NO	APPL-DATE
JP 04367457A	N/A	1991JP-0155383	May 31, 1991

INT-CL (IPC): B65D073/02

ABSTRACTED-PUB-NO: JP 04367457A

BASIC-ABSTRACT:

The cover tape film is formed as follows: (a) a transparent conductive resin film comprising tin oxide and/or indium oxide film fine powder with average grain dia. up to 0.3 microns and a binder resin is formed on the surface of a transparent plastic film; and (b) A hot melt adhesive layer is provided on the rear of the film. The mounting parts packaging body comprises; the cover tape film and a carrier tape with recesses for housing mounting parts in an antistatic or conductive resin sheet. The carrier tape is heat-sealed by the hot melt adhesive layer for easy opening.

USE/ADVANTAGE - The cover tape film is used for a mounting parts packaging body for housing various electronic parts, precision, or ICs. The packaging body has no increase in surface resistance even if the packaging body is continuously exposed to high temp. and high humidity. It is transparent, generates no sticking and requires no cleaning for a long period.

CHOSEN-DRAWING: Dwg.0/2

TITLE-TERMS: COVER TAPE FILM PACKAGE MOUNT ELECTRONIC PART COMPRISE HOT MELT ADHESIVE BACKING TRANSPARENT PLASTIC FILM CONDUCTING LAYER BIND CONTAIN TIN OXIDE INDIUM OXIDE FINE PARTICLE

DERWENT-CLASS: A92 Q34

CPI-CODES: A09-A02; A09-A03; A11-C01A; A11-C04B2; A12-E07C; A12-S06;

POLYMER-MULTIPUNCH-CODES-AND-KEY-SERIALS:

Key Serials: 0141 0150 0231 2211 2319 2426 2437 2513 2542 2551 2595 2600 2649  
2651 2682 2684 2737 2740 2774 3253 3279  
Multipunch Codes: 014 04- 08& 09- 15- 17& 308 331 342 381 393 431 435 443 479  
506 509 516 523 541 55& 575 58& 592 593 597 600 609 623 627 628 725 014 04- 331  
36& 381 431 443 506 509 516 523 541 55& 58& 597 600 609 623 627 628

SECONDARY-ACC-NO:

CPI Secondary Accession Numbers: C1993-018728

Non-CPI Secondary Accession Numbers: N1993-031740

(19)日本国特許庁(JP)

(12) 公開特許公報(A)

(11)特許出願公開番号

特開平5-311061

(43)公開日 平成5年(1993)11月22日

(51)Int.Cl. <sup>5</sup>	識別記号	庁内整理番号	F I	技術表示箇所
C 0 8 L 69/00	L P P	8416-4 J		
C 0 8 K 3/04	K K H	7242-4 J		
// H 0 1 B 1/24		Z 7244-5 G		
(C 0 8 L 69/00 23: 08)				

審査請求 未請求 請求項の数 2(全 6 頁)

(21)出願番号 特願平4-142001

(22)出願日 平成4年(1992)5月8日

(71)出願人 000003296

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(72)発明者 横山 聡

東京都町田市旭町3丁目5番1号 電気化学工業株式会社総合研究所内

(72)発明者 鍋田 健司

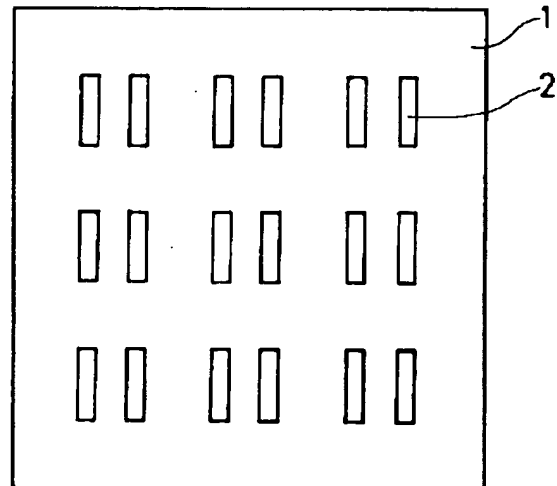
東京都町田市旭町3丁目5番1号 電気化学工業株式会社総合研究所内

(54)【発明の名称】 耐熱導電性樹脂組成物及びその成形品

(57)【要約】

【目的】 耐熱導電性樹脂組成物として、制電特性、機械的物性及び高温加熱下での寸法安定性に優れ、また卓越した衝撃強度を有する帯電・静電気防止用の成形品に利用できる樹脂組成のものを得る。

【構成】 ポリカーボネート樹脂100重量部、カーボンブラック10～45重量部及びエチレン-アクリル酸エステル共重合体1～20重量部からなる樹脂組成物。





DERWENT-ACC-NO: 1993-411035

DERWENT-WEEK: 199351

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TITLE: Heat resistant electroconductive resin compsn. for  
moulded prod. - contains polycarbonate resin, carbon  
black and ethylene-acrylic-ester copolymer resin

PATENT-ASSIGNEE: DENKI KAGAKU KOGYO KK[ELED]

PRIORITY-DATA: 1992JP-0142001 (May 8, 1992)

PATENT-FAMILY:

PUB-NO	PUB-DATE	LANGUAGE	PAGES	MAIN-IPC
JP 05311061 A	November 22, 1993	N/A	006	C08L 069/00

APPLICATION-DATA:

PUB-NO	APPL-DESCRIPTOR	APPL-NO	APPL-DATE
JP 05311061A	N/A	1992JP-0142001	May 8, 1992

INT-CL (IPC): C08K003/04, C08L069/00, H01B001/24, C08L023:08,  
C08L069/00

ABSTRACTED-PUB-NO: JP 05311061A

BASIC-ABSTRACT:

The resin compsn. contains 100 pts. wt. of (A) polycarbonate resin, 10 to 45  
pts. wt. of (B) C black and 1 to 20 pts. wt. of (C) ethylene-acrylic ester  
copolymer resin as reinforcing material.

(A) has a viscosity average mol.wt. of 10,000 to 50,000, pref. 25,000 to  
30,000. (B) has a particle dia. of 10 to 300 microns, a DBP absorption of 300  
to 500 cc/100 mg. and has a specific surface area of 20 to 1,800 g/m<sup>2</sup>, and is  
pref. furnace black. Pref. (C) is ethylene-ethyl acrylate copolymer resin  
having an ethyl acrylate content of 10 to 50 mol. %. The resin compsn. may  
contain antioxidant and lubricant in 1 to 10 and 0.1 to 10 pts. wt.  
respectively per 100 pts. wt. of (A).

ADVANTAGE - The resin compsn. has excellent antistatic and mechanical  
properties, high dimensional stability under heating at elevated temp. and high  
impact strength. It is useful for antistatic moulded prod. such as plastic  
tray for transport, storage and drying of semiconductor integrated circuit  
device.

CHOSEN-DRAWING: Dwg.1/1

TITLE-TERMS: HEAT RESISTANCE ELECTROCONDUCTING RESIN COMPOSITION MOULD PRODUCT  
CONTAIN POLYCARBONATE RESIN CARBON BLACK POLYETHYLENE POLYACRYLIC  
POLYESTER COPOLYMER RESIN

DERWENT-CLASS: A23 A85 L03 U11 X12 X25

CPI-CODES: A04-F06B; A04-G08A; A05-E06A; A08-R03; A08-R08; A09-A01A; A09-A03;  
A12-S08E; L03-A02E; L04-D10;

EPI-CODES: U11-A07; X12-D01X; X25-S;

UNLINKED-DERWENT-REGISTRY-NUMBERS: 5085U

ENHANCED-POLYMER-INDEXING:

Polymer Index [1.1]

017 ; H0022 H0011 ; R00326 G0044 G0033 G0022 D01 D02 D12 D10 D51  
D53 D58 D82 ; G0340\*R G0339 G0260 G0022 D01 D12 D10 D51 D53 D58  
D63 F41 ; S9999 S1434 ; A999 A782 ; A999 A419 ; P1150 ; P0088

Polymer Index [1.2]

017 ; H0022 H0011 ; R00326 G0044 G0033 G0022 D01 D02 D12 D10 D51  
D53 D58 D82 ; R01126 G0340 G0339 G0260 G0022 D01 D11 D10 D12 D51  
D53 D58 D63 D85 F41 ; S9999 S1434 ; A999 A782 ; A999 A419 ; P1150  
; P0088 ; P0180

Polymer Index [1.3]

017 ; ND04 ; K9745\*R ; B9999 B3305 B3292 B3190 ; B9999 B3747\*R ;  
B9999 B3758\*R B3747 ; B9999 B4159 B4091 B3838 B3747 ; Q9999 Q8571  
Q8366 ; Q9999 Q7476 Q7330 ; K9461 ; B9999 B3178 ; B9999 B4682 B4568

Polymer Index [1.4]

017 ; A999 A497 A486 ; A999 A340\*R

Polymer Index [1.5]

017 ; R05085 D00 D09 C\* 4A ; A999 A237 ; A999 A760 ; S9999 S1456\*R

(19) 日本国特許庁 (J P)

(12) 公開特許公報 (A)

(11) 特許出願公開番号

特開平6-350021

(43) 公開日 平成6年(1994)12月22日

(51) Int.Cl. <sup>5</sup>	識別記号	庁内整理番号	F I	技術表示箇所
H 0 1 L 25/00	B			
23/50	X			
23/60				

H 0 1 L 23/ 56 B

審査請求 未請求 請求項の数 1 O L (全 3 頁)

(21) 出願番号 特願平5-140315

(22) 出願日 平成5年(1993)6月11日

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(74) 代理人 弁理士 小川 勝男

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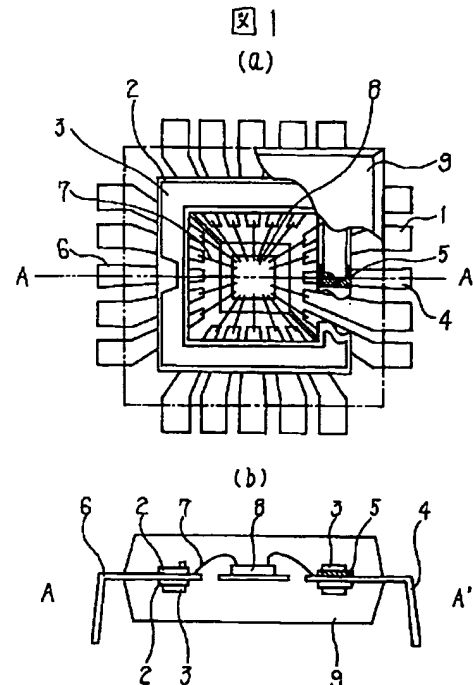
(54) 【発明の名称】 リードフレーム

(57) 【要約】

【目的】 半導体装置用のリードフレームにおいて、リードフレームと電源の間に容量を持たせ、このリードフレームを用いることによってICの静電耐圧を向上させることが目的である。

【構成】 42合金等でできたリードフレームの本体1の上に絶縁物の薄膜2、さらにその上に導体3をおきこの絶縁物の薄膜を任意のリード上では、導体とすることによって、そのリードと絶縁物上の導体を接続する。

【効果】 本発明によってICの静電耐圧向上を行うことが簡便になる。またリードフレームを両側から導体ではさみ、その電位を異なる電源とした場合、電源間にも容量が付くため電源ノイズを低減することが出来る。



DERWENT-ACC-NO: 1995-072033

DERWENT-WEEK: 199510

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TITLE: Lead frame for plastic package type IC(s) - has lead over which thin film of insulator and conductor are deposited and connected to IC chip to improve electrostatic breakdown resistance

PATENT-ASSIGNEE: HITACHI LTD(HITA)

PRIORITY-DATA: 1993JP-0140315 (June 11, 1993)

PATENT-FAMILY:

PUB-NO	PUB-DATE	LANGUAGE	PAGES	MAIN-IPC
JP 06350021 A	December 22, 1994	N/A	003	H01L 025/00

APPLICATION-DATA:

PUB-NO	APPL-DESCRIPTOR	APPL-NO	APPL-DATE
JP 06350021A	N/A	1993JP-0140315	June 11, 1993

INT-CL (IPC): H01L023/50, H01L023/60 , H01L025/00

ABSTRACTED-PUB-NO: JP 06350021A

BASIC-ABSTRACT:

The lead frame has a main part (1) made of a metal alloy. A lead is connected to the IC chip (8). A thin film (2) of an insulator, is deposited on this lead. Another thin film (3) of an electric conductor is laid over this structure. The lead is then connected to the electric conductor.

ADVANTAGE - Improves electrostatic breakdown resistance. Reduces power supply noise since capacitance is connected between power supplies.

CHOSEN-DRAWING: Dwg.1/1

TITLE-TERMS: LEAD FRAME PLASTIC PACKAGE TYPE IC LEAD THIN FILM INSULATE  
CONDUCTOR DEPOSIT CONNECT IC CHIP IMPROVE ELECTROSTATIC BREAKDOWN  
RESISTANCE

DERWENT-CLASS: U11

EPI-CODES: U11-D03A1A; U11-D03C1;

SECONDARY-ACC-NO:

Non-CPI Secondary Accession Numbers: N1995-056829

(19) 日本国特許庁 (J P)

(12) 公開特許公報 (A)

(11) 特許出願公開番号

特開平9-172059

(43) 公開日 平成9年(1997)6月30日

(51) Int.Cl. <sup>6</sup>	識別記号	庁内整理番号	F I	技術表示箇所
H 0 1 L 21/68			H 0 1 L 21/68	U
B 6 5 D 85/86		0333-3E	B 6 5 D 85/38	J

審査請求 未請求 請求項の数 4 O L (全 2 頁)

(21) 出願番号 特願平7-328709

(22) 出願日 平成7年(1995)12月18日

(71) 出願人 390009667

日本プレシジョン・サーキット株式会社  
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栃木県那須郡塩原町大字下田野531-1

日本プレシジョン・サーキット株式会社内

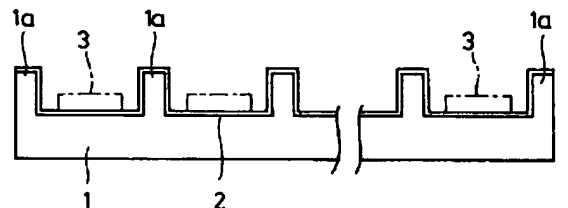
(74) 代理人 弁理士 松田 和子

(54) 【発明の名称】 IC用チップトレイ

(57) 【要約】

【課題】 ICを静電気から確実に保護することが可能なIC用チップトレイを提供する。

【解決手段】 IC用チップトレイの基体1の表面に金属層2をコーティングしてシート抵抗を大幅に減少させた。また、基体1の表面を凸凹状に形成して金属層2との密着性を向上させた。



DERWENT-ACC-NO: 1997-391235

DERWENT-WEEK: 199736

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TITLE: Chip tray for IC - has base which surface is coated with metal layer thereby reducing sheet resistance of surface

PATENT-ASSIGNEE: NIPPON PRECISION CIRCUITS KK[NIPRN]

PRIORITY-DATA: 1995JP-0328709 (December 18, 1995)

PATENT-FAMILY:

PUB-NO	PUB-DATE	LANGUAGE	PAGES	MAIN-IPC
JP 09172059 A	June 30, 1997	N/A	002	H01L 021/68

APPLICATION-DATA:

PUB-NO	APPL-DESCRIPTOR	APPL-NO	APPL-DATE
JP 09172059A	N/A	1995JP-0328709	December 18, 1995

INT-CL (IPC): B65D085/86, H01L021/68

ABSTRACTED-PUB-NO: JP 09172059A

BASIC-ABSTRACT:

The chip tray has a base (1) which is coated with metal layer (2) thereby reducing sheet resistance of the surface.

The surface of the base is in the shape of unevenness.

ADVANTAGE - Performs guarding of IC from static.

CHOSEN-DRAWING: Dwg.1/1

TITLE-TERMS: CHIP TRAY IC BASE SURFACE COATING METAL LAYER REDUCE SHEET RESISTANCE SURFACE

ADDL-INDEXING-TERMS:

ELECTROCONDUCTIVE PLASTICS

DERWENT-CLASS: Q34 U11

EPI-CODES: U11-F02A4;

SECONDARY-ACC-NO:

Non-CPI Secondary Accession Numbers: N1997-325694

(19) 日本国特許庁 (J P)

(12) 公開特許公報 (A)

(11) 特許出願公開番号

特開平11-181181

(43) 公開日 平成11年(1999) 7月6日

(51) Int.Cl. <sup>8</sup>	識別記号	F I
C 0 8 L 23/10		C 0 8 L 23/10
C 0 8 K 3/00		C 0 8 K 3/00
	3/04	3/04
	7/06	7/06
	7/14	7/14

審査請求 未請求 請求項の数 4 O L (全 6 頁) 最終頁に続く

(21) 出願番号	特願平9-356923	(71) 出願人	000002141 住友ベークライト株式会社 東京都品川区東品川 2 丁目 5 番 8 号
(22) 出願日	平成 9 年 (1997) 12 月 25 日	(72) 発明者	中馬 敏秋 東京都品川区東品川 2 丁目 5 番 8 号 住友 ベークライト株式会社内

(54) 【発明の名称】 樹脂組成物

(57) 【要約】

【課題】 射出成形などの成形加工性に良好であり、耐熱性、高機械強度、および帯電防止性に優れた樹脂組成物を提供すること。

【解決手段】 (a) ポリプロピレン樹脂 100 重量部に対し、(b) ガラス繊維 40～60 重量部 (c) 無機フィラー 30～50 重量部 (d) カーボンブラック及び／又はカーボン繊維 10～90 重量部 (e) 変性ポリプロピレン樹脂 0.5～20 重量部を配合してなる樹脂組成物。

DERWENT-ACC-NO: 1999-439638

DERWENT-WEEK: 199941

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TITLE: Resin composition with good mouldability - comprises polypropylene resin, glass fibre, inorganic fillers, carbon black and/or carbon fibre, and modified polypropylene resin

PATENT-ASSIGNEE: SUMITOMO BAKELITE CO LTD(SUMB)

PRIORITY-DATA: 1997JP-0356923 (December 25, 1997)

PATENT-FAMILY:

PUB-NO	PUB-DATE	LANGUAGE	PAGES	MAIN-IPC
JP 11181181 A	July 6, 1999	N/A	006	C08L 023/10

APPLICATION-DATA:

PUB-NO	APPL-DESCRIPTOR	APPL-NO	APPL-DATE
JP 11181181A	N/A	1997JP-0356923	December 25, 1997

INT-CL (IPC): C08K003/00, C08K003/04, C08K007/06, C08K007/14, C08L023/10, C08L023/10, C08L023:26

ABSTRACTED-PUB-NO: JP 11181181A

BASIC-ABSTRACT:

Resin composition comprises (A) 100 pts. wt. of polypropylene resin with (B) 40-60 pts.wt. of glass fibre, (C) 30-50 pts. wt. of inorganic fillers, (D) 10-90 pts. wt. of carbon black and/or carbon fibre, and (E) 0.5-20 pts. wt. of modified polypropylene resin compounded.

USE - The resin compsn. is used as jigs for carrying electronic appts. and IC and packaging materials.

ADVANTAGE - The resin compsn. has good mouldability and antistatic properties and high thermal strength and mechanical strength.

CHOSEN-DRAWING: Dwg.0/0

TITLE-TERMS: RESIN COMPOSITION MOULD COMPRISE POLYPROPYLENE RESIN GLASS FIBRE  
INORGANIC FILL CARBON BLACK CARBON FIBRE MODIFIED POLYPROPYLENE  
RESIN

DERWENT-CLASS: A17 A85 A92 U11

CPI-CODES: A04-G03B; A07-A02; A08-R01;

EPI-CODES: U11-A07;

ENHANCED-POLYMER-INDEXING:

Polymer Index [1.1]

018 ; R00964 G0044 G0033 G0022 D01 D02 D12 D10 D51 D53 D58 D83 ;  
H0000 ; H0011\*R ; P1150 ; P1343

Polymer Index [1.2]

018 ; G0044\*R G0033 G0022 D01 D02 D12 D10 D51 D53 D58 ; R00964 G0044  
G0033 G0022 D01 D02 D12 D10 D51 D53 D58 D83 ; H0011\*R ; P1150

Polymer Index [1.3]

018 ; ND04 ; B9999 B3623 B3554 ; K9892 ; K9449 ; Q9999 Q7330\*R ;  
Q9999 Q7476 Q7330 ; B9999 B4091\*R B3838 B3747 ; B9999 B4148 B4091  
B3838 B3747 ; B9999 B4159 B4091 B3838 B3747 ; B9999 B4171 B4091  
B3838 B3747 ; B9999 B3601 B3554 ; B9999 B5594 B5572

Polymer Index [1.4]

018 ; G2891 D00 Si 4A ; A999 A419 ; S9999 S1070\*R ; B9999 B5254  
B5243 B4740

Polymer Index [1.5]

018 ; D00 G3190 R01541 F80 O\* 6A Mg 2A Si 4A ; G3010 D00 F80 Al  
3A Si 4A O\* 6A ; A999 A237

Polymer Index [1.6]

018 ; R05085 D00 D09 C\* 4A ; R05086 D00 D09 C\* 4A ; A999 A602 A566  
; S9999 S1070\*R

Polymer Index [1.7]

018 ; A999 A033

Polymer Index [2.1]

018 ; R00964 G0044 G0033 G0022 D01 D02 D12 D10 D51 D53 D58 D83 ;  
H0000 ; H0011\*R ; M9999 M2391 ; M9999 M2062 ; A999 A782 ; A999 A033  
; P1150 ; P1343